

پیوند یا ضدپیوند؟

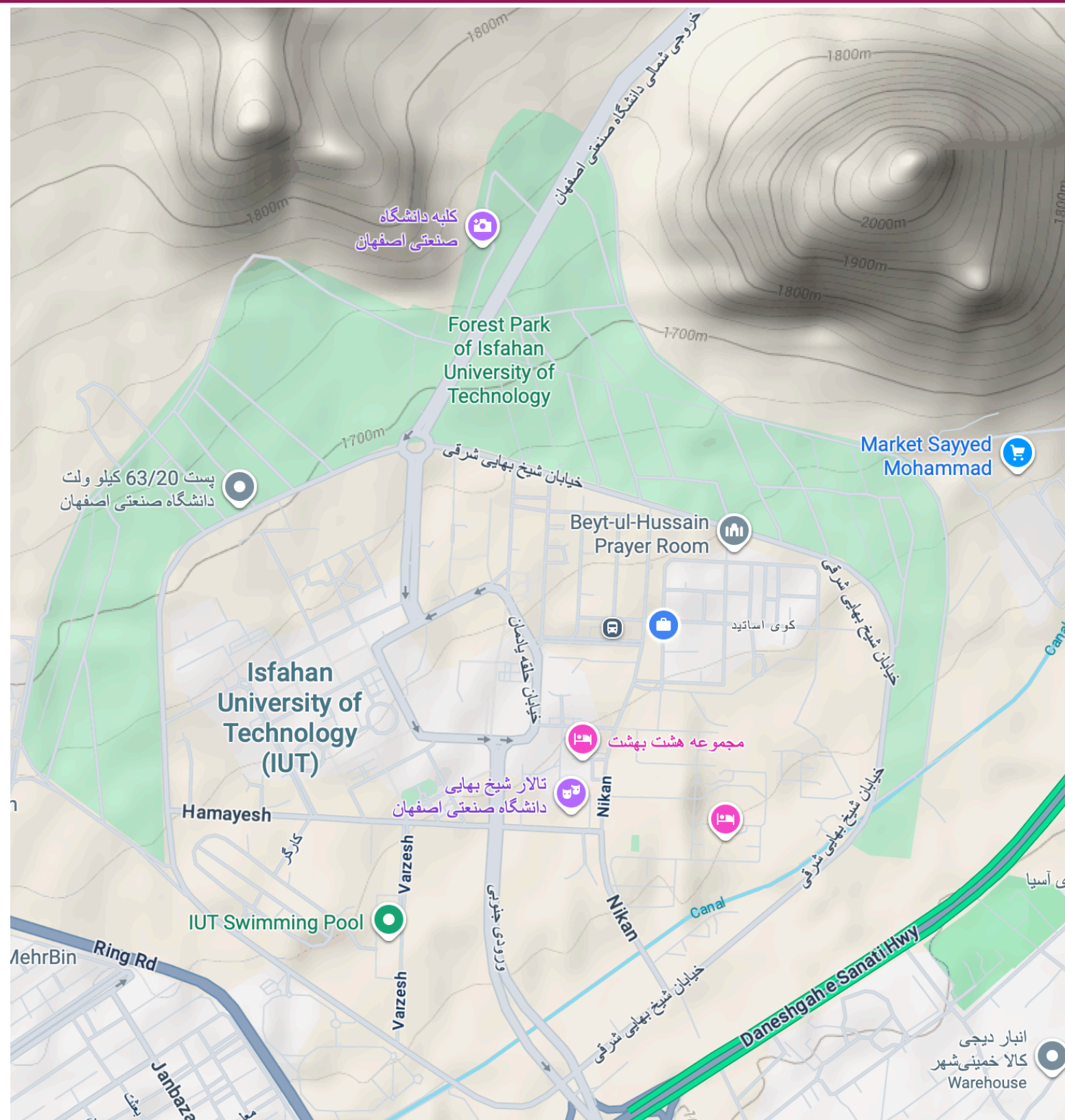
اسماعیل عبدالحسینی سارسی

گروه شبیه سازی کوانتومی مواد*، دانشکده فیزیک، دانشگاه صنعتی اصفهان



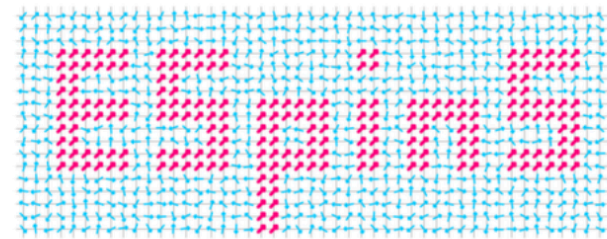
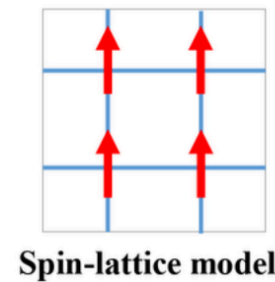
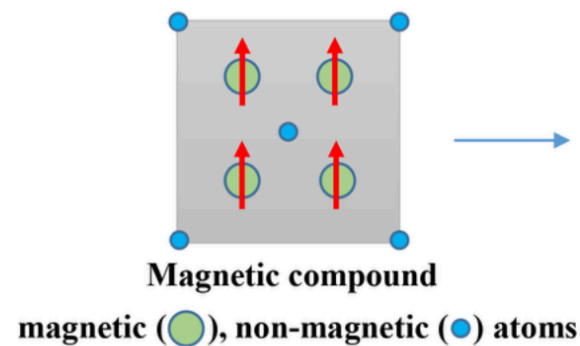
سومین
مدرسه
تابستانه
نوفت در فیزیک
از فیزیک

دانشگاه صنعتی اصفهان





ESpinS: A program for classical Monte-Carlo simulations of spin systems

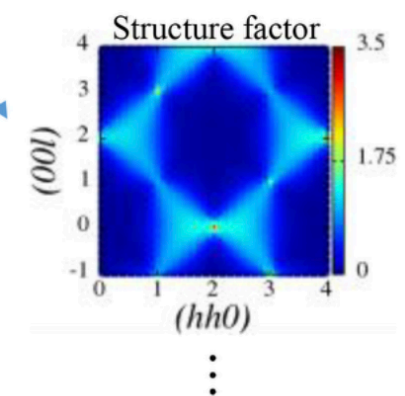
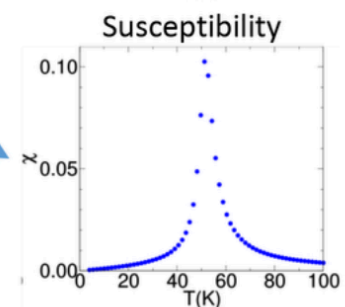
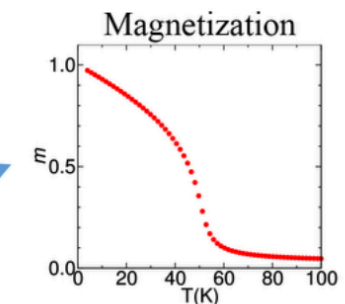


<https://github.com/nafiserb/ESpinS>

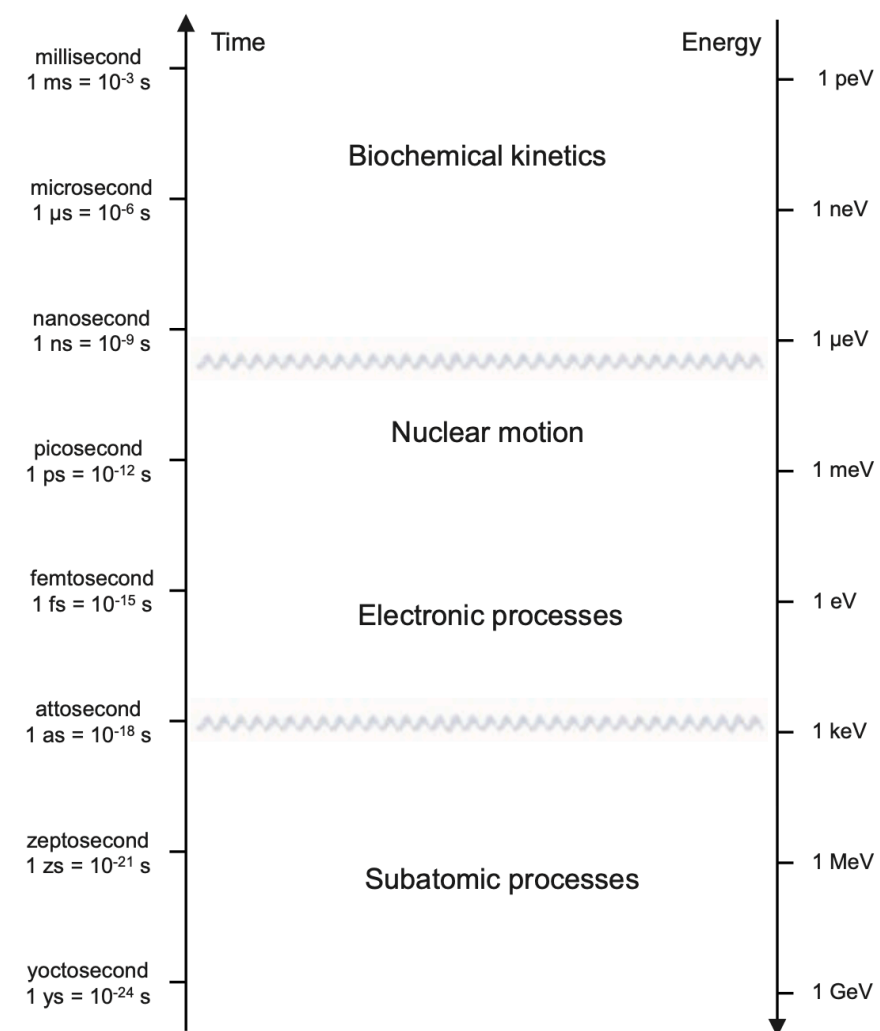
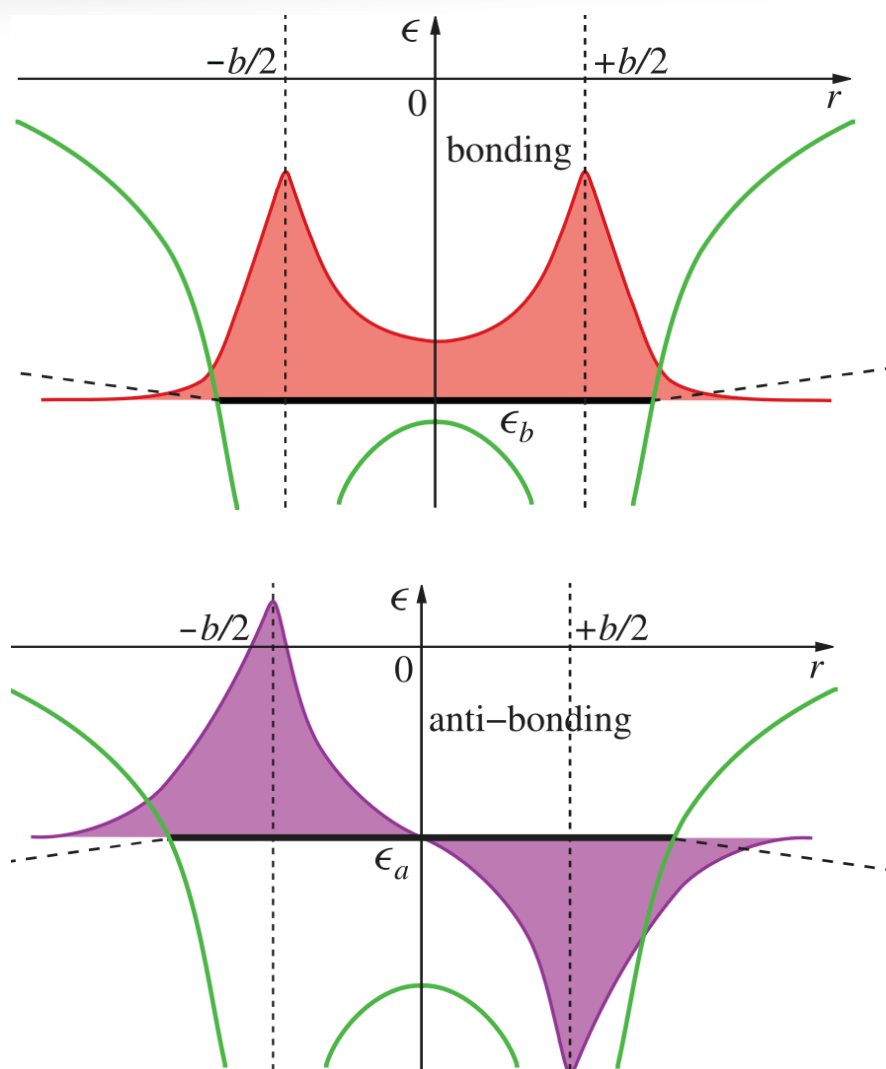
Spin model Hamiltonian:

$$\mathcal{H} = -\frac{1}{2} \sum_{i,j} J_{ij} \mathbf{S}_i \cdot \mathbf{S}_j + \frac{1}{2} \sum_{i,j} B_{ij} (\mathbf{S}_i \cdot \mathbf{S}_j)^2 + \frac{1}{2} \sum_{i,j} \mathbf{D}_{ij} \cdot (\mathbf{S}_i \times \mathbf{S}_j) + \Delta \sum_i (\hat{z}_i \cdot \mathbf{S}_i)^2$$

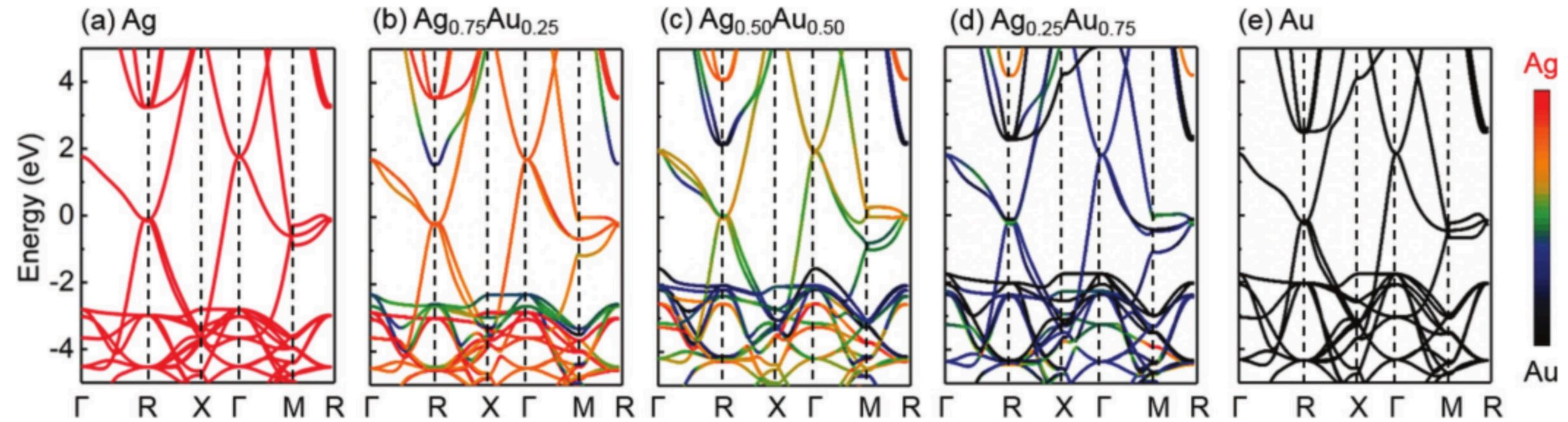
N. Rezaei, M. Alaei and H. Akbarzadeh, Comput. Mater. Sci. 202, 110947 (2022).



پیوند یا ضدپیوند؟



اسپاگتی : ساختار نواری



پیوند دو اتم هیدروژن

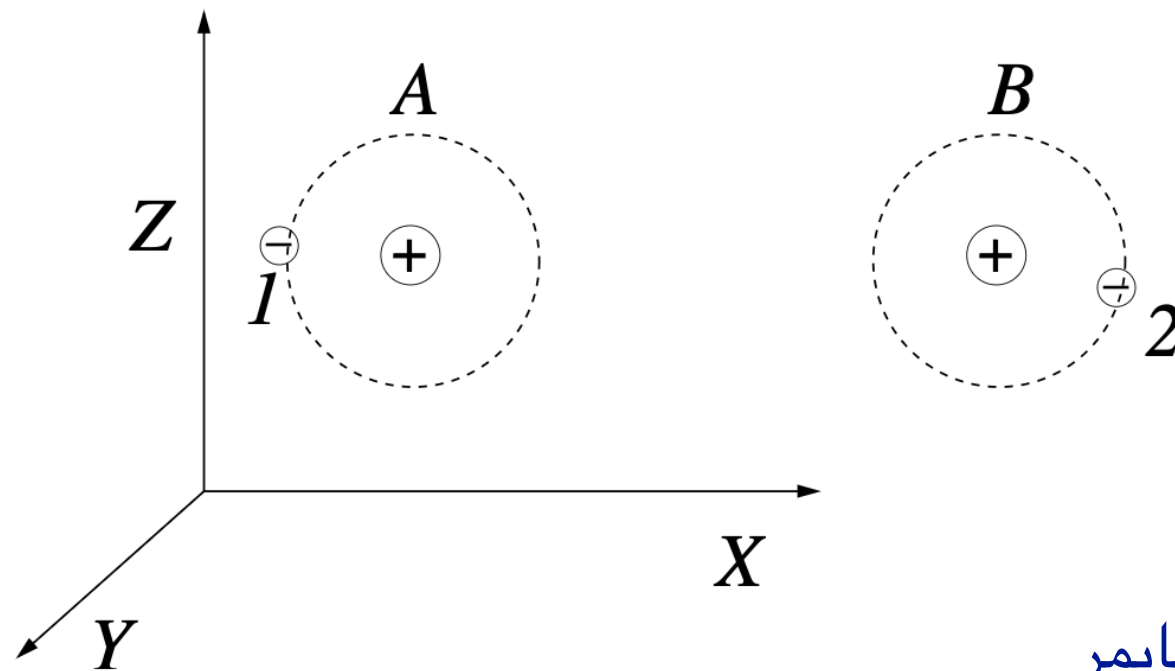
ساختار نواری زنجیر اتمی

بلور 2D

ساختار نواری گرافین

پروژه : اثر شکست تقارن وارونی بر ساختار نواری

مولکول هیدروژن



معادله شرودینگر

$$H\psi(\vec{r}_1, \vec{r}_2) = E\psi(\vec{r}_1, \vec{r}_2)$$

هامیلتونی سیستم با در نظر گرفتن تقریب بورن-اپنهایمر

$$H = \left(-\frac{\hbar^2 \nabla_1^2}{2m} - \frac{e^2}{|\vec{r}_1 - \vec{R}_A|} \right) + \left(-\frac{\hbar^2 \nabla_2^2}{2m} - \frac{e^2}{|\vec{r}_2 - \vec{R}_B|} \right) - \frac{e^2}{|\vec{r}_1 - \vec{R}_B|} - \frac{e^2}{|\vec{r}_2 - \vec{R}_A|}$$

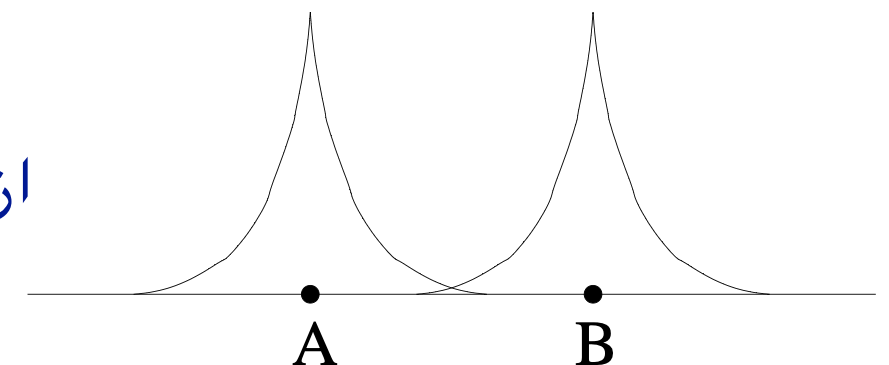
$$H = H_A + H_B - \frac{e^2}{|\vec{r}_1 - \vec{R}_B|} - \frac{e^2}{|\vec{r}_2 - \vec{R}_A|}$$

$$\langle \vec{r} | \psi \rangle = \psi(\vec{r}) = \frac{1}{\sqrt{\pi}} \left(\frac{Z}{a_0} \right)^{3/2} e^{-r/a_0}$$

$$H_A|1\rangle = \epsilon_{1s}|1\rangle \quad \text{and} \quad H_B|2\rangle = \epsilon_{1s}|2\rangle$$

اوربیتال
تراز

از کوانتوم بلد هستیم



$$|\psi\rangle = \sum_1^2 \psi_i |i\rangle = \psi_1 |1\rangle + \psi_2 |2\rangle$$

تابع موج بر حسب ترکیب خطی اوربیتال‌های اتمی

انجام کاری معادل Ritz Principle

$$\begin{cases} \langle 1|H(\psi_1|1\rangle + \psi_2|2\rangle) = E\langle 1|(\psi_1|1\rangle + \psi_2|2\rangle) \\ \langle 2|H(\psi_1|1\rangle + \psi_2|2\rangle) = E\langle 2|(\psi_1|1\rangle + \psi_2|2\rangle) \end{cases} \longrightarrow \begin{cases} \langle 1|H|1\rangle\psi_1 + \langle 1|H|2\rangle\psi_2 = E\psi_1 \\ \langle 2|H|1\rangle\psi_1 + \langle 2|H|2\rangle\psi_2 = E\psi_2 \end{cases}$$

$$\begin{cases} \epsilon_0\psi_1 + \gamma\psi_2 = E\psi_1 \\ \gamma\psi_1 + \epsilon_0\psi_2 = E\psi_2 \end{cases} \longrightarrow \begin{pmatrix} \epsilon_0 & \gamma \\ \gamma & \epsilon_0 \end{pmatrix} \begin{pmatrix} \psi_1 \\ \psi_2 \end{pmatrix} = E \begin{pmatrix} \psi_1 \\ \psi_2 \end{pmatrix}$$

$$\det \begin{pmatrix} \epsilon_0 - E & \gamma \\ \gamma & \epsilon_0 - E \end{pmatrix} = 0$$

$$(\epsilon_0 - E)^2 - \gamma^2 = 0$$

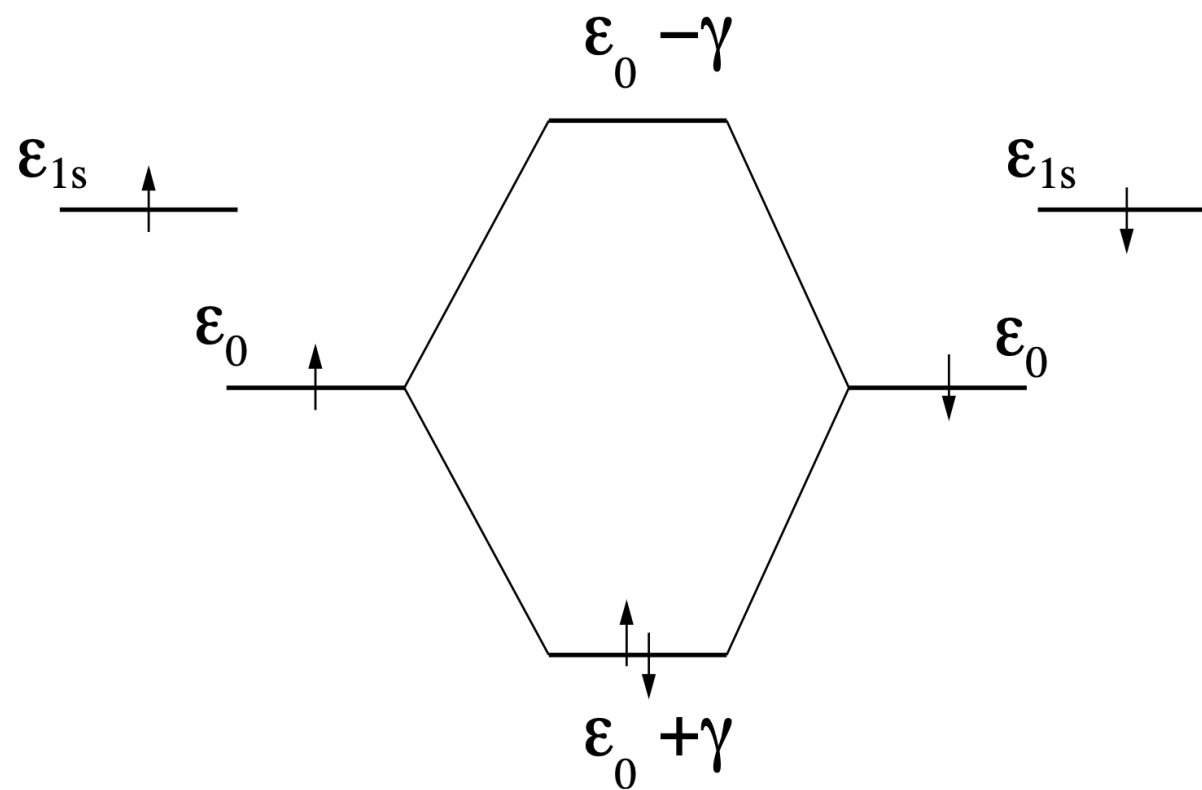
$$E_{\text{bond}} = \epsilon_0 + \gamma$$

and

$$E_{\text{anti}} = \epsilon_0 - \gamma$$

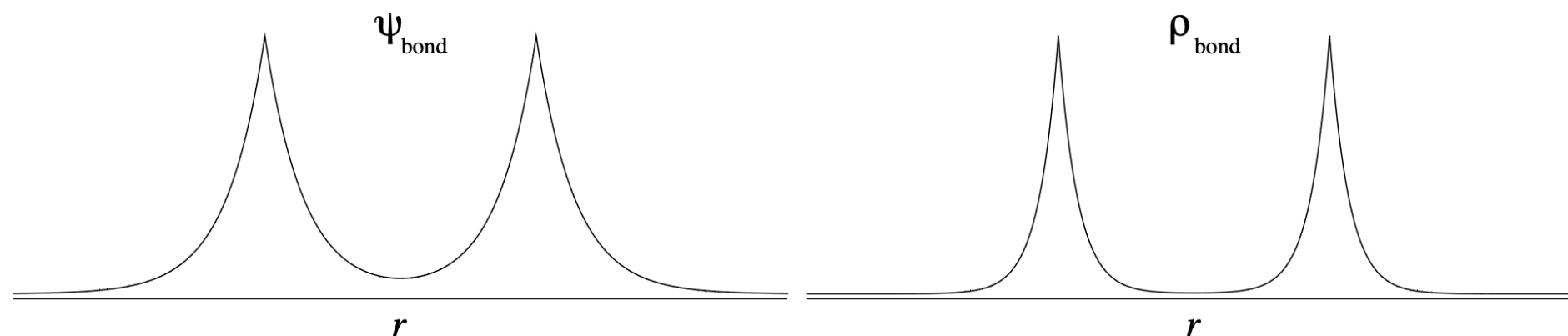
ترازهای انرژی مولکول هیدروژن

$$E_{\text{bond}} = \epsilon_0 + \gamma \quad |\psi_{\text{bond}}\rangle = \frac{1}{\sqrt{2}}(|1\rangle + |2\rangle)$$
$$E_{\text{anti}} = \epsilon_0 - \gamma \quad |\psi_{\text{anti}}\rangle = \frac{1}{\sqrt{2}}(|1\rangle - |2\rangle)$$



اوربیتال‌های مولکولی مولکول هیدروژن

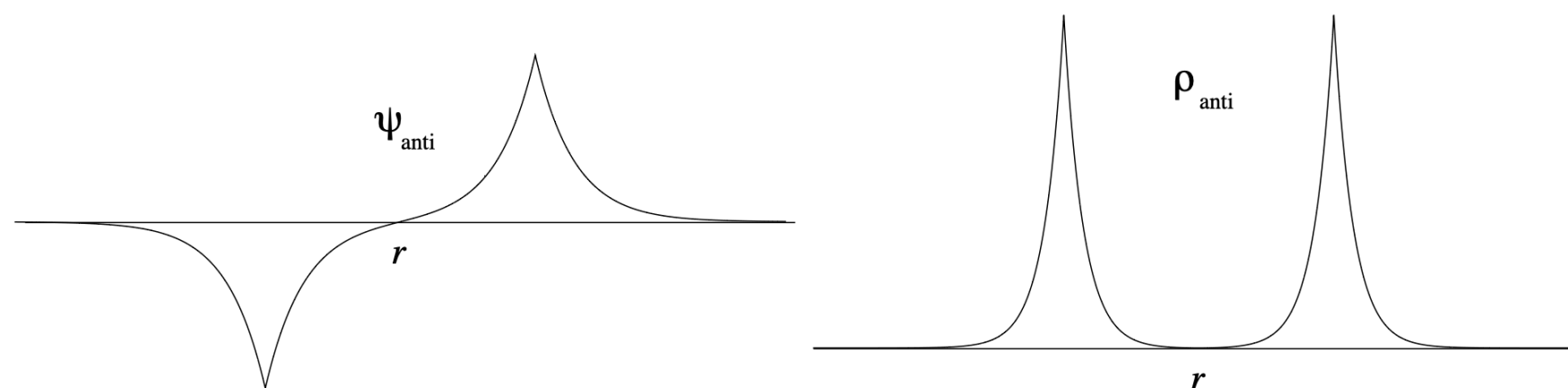
Bonding State



There is charge between the two H atoms → Bond

$$|\psi_{\text{bond}}\rangle = \frac{1}{\sqrt{2}}(|1\rangle + |2\rangle)$$

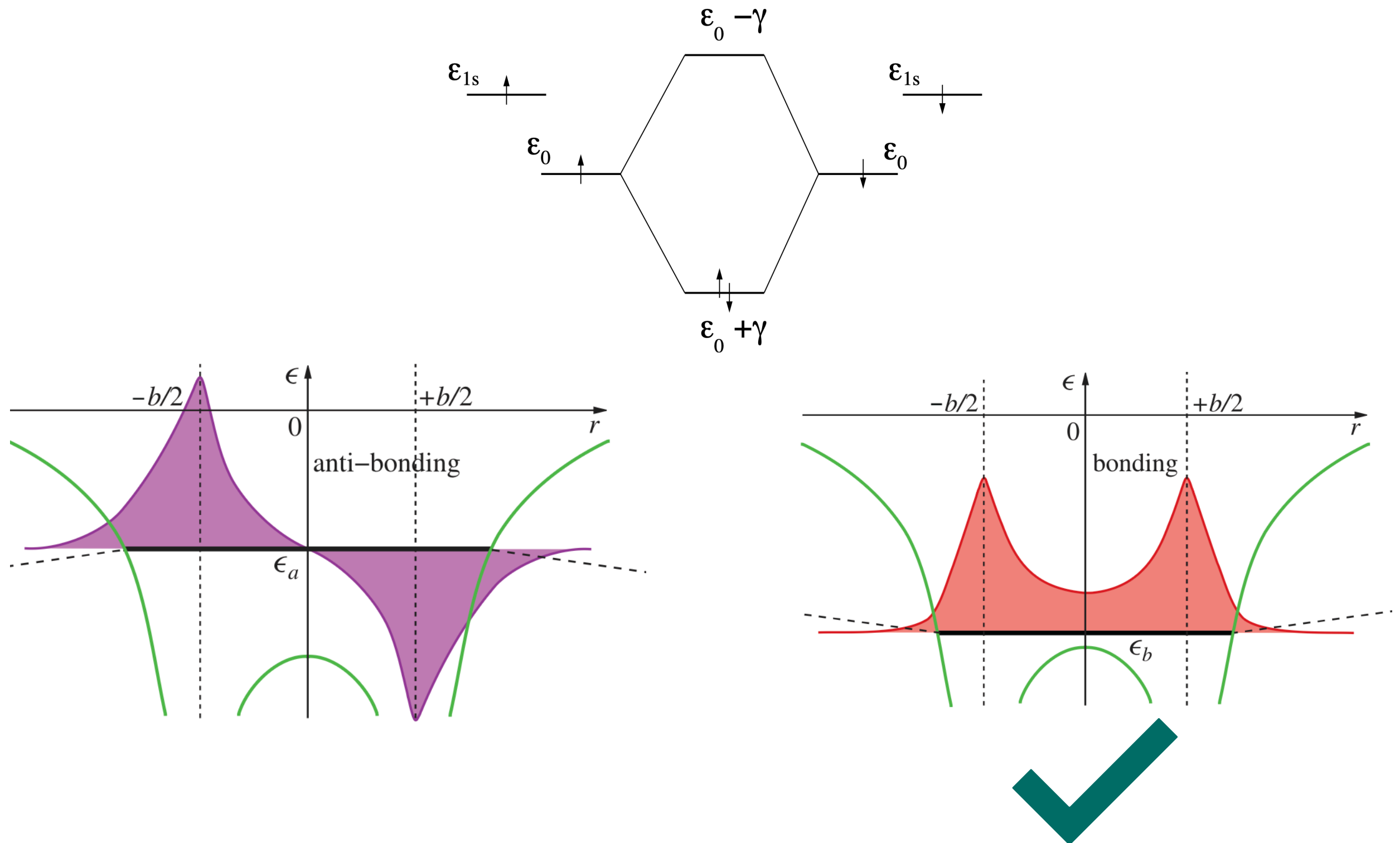
Antibonding State



No charge between the two atoms → No bond

$$|\psi_{\text{anti}}\rangle = \frac{1}{\sqrt{2}}(|1\rangle - |2\rangle)$$

نتیجه: حالت پیوندی دارای انرژی کمتر



$$H = \frac{1}{2M} \sum_{i=1}^{N_n} \mathbf{P}_i^2 + \frac{1}{2m_0} \sum_{j=1}^{N_e} \mathbf{p}_j^2 + \frac{Z^2}{2} \sum_{i,j=1, i \neq j}^{N_n} V_c(\mathbf{R}_i - \mathbf{R}_j) - Z \sum_{i=1}^{N_n} \sum_{j=1}^{N_e} V_c(\mathbf{r}_j - \mathbf{R}_i) + \frac{1}{2} \sum_{i,j=1, i \neq j}^{N_e} V_c(\mathbf{r}_i - \mathbf{r}_j).$$

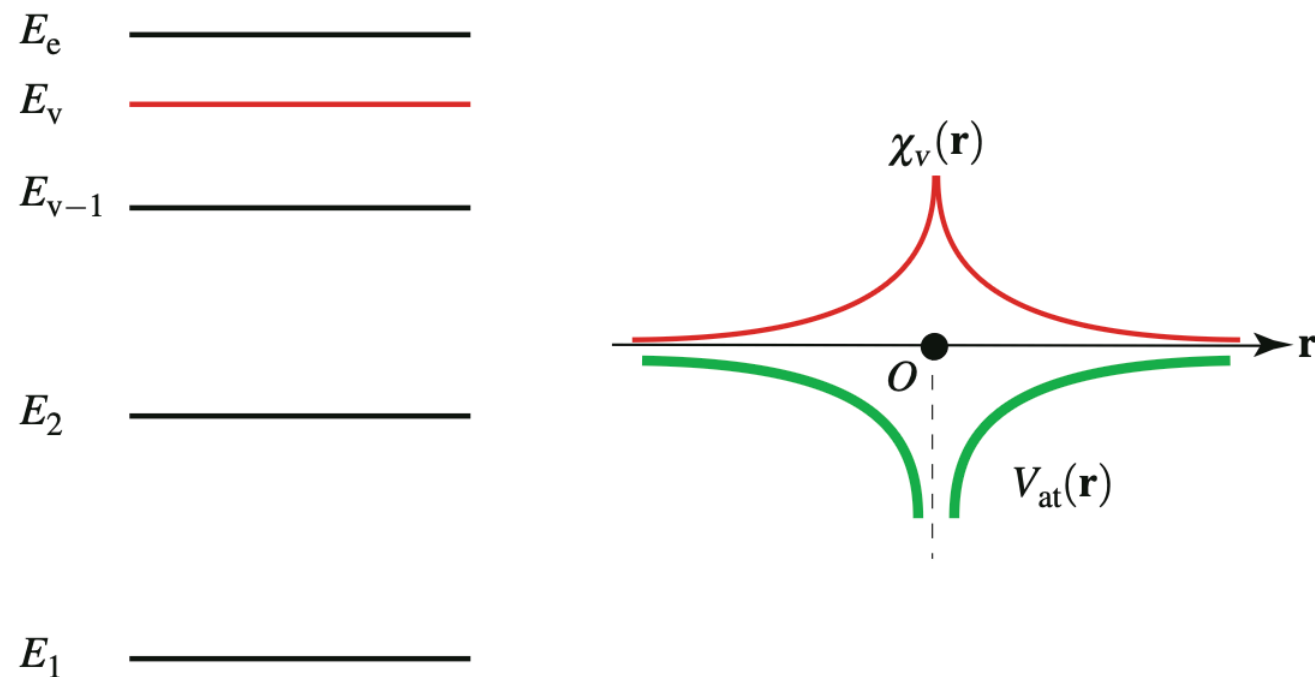
تقریب بورن اپنهاایمر و تقریب مقدار میانگین

تقریب هارتری، هارتری-فوک و تنگابست-رهیافت DFT

معادله شرودینگر تک ذره‌ای

$$\left[\frac{\mathbf{p}^2}{2m_0} + V_{at}(\mathbf{r}) \right] \chi_n(\mathbf{r}) = E_n \chi_n(\mathbf{r})$$

هامیلتونی عمومی جامدات - معادله شرودینگر بس ذره‌ای



LCAO

$$\psi_k(\mathbf{r}) = \frac{1}{\sqrt{N_n}} \sum_{l=1}^{N_n} a_{k,l} \chi_v(\mathbf{r} - \mathbf{R}_l)$$

$$|\psi_k\rangle = \frac{1}{\sqrt{N_n}} \sum_{l=1}^{N_n} a_{k,l} |\mathbf{R}_l\rangle$$

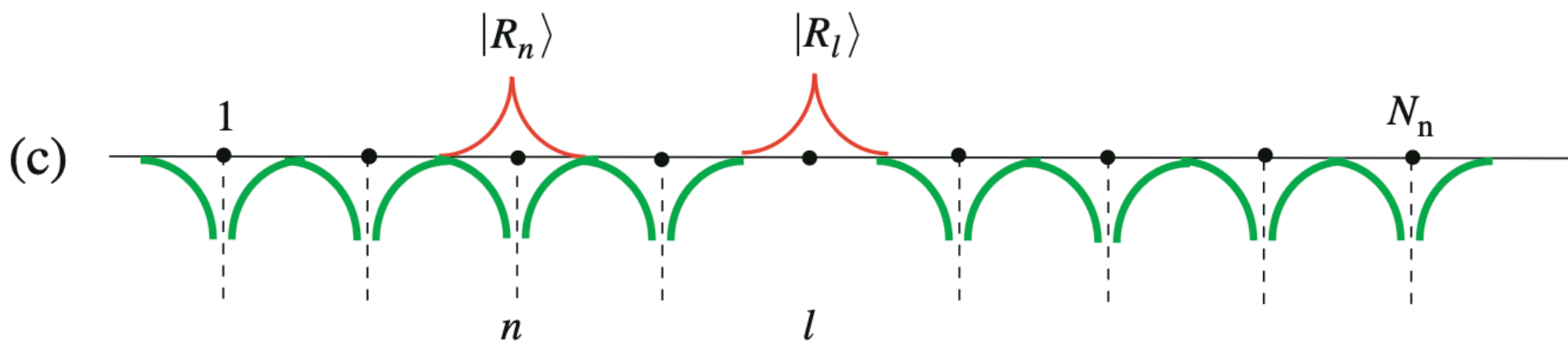
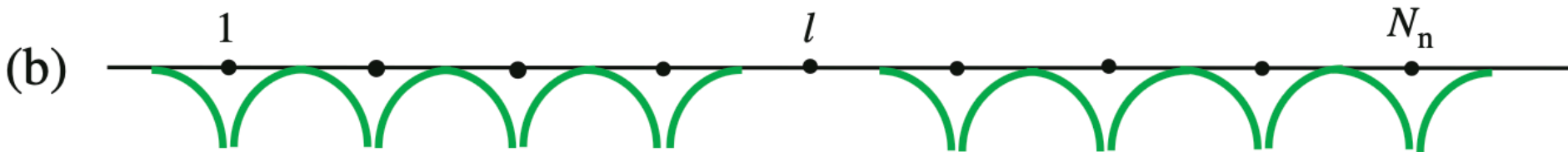
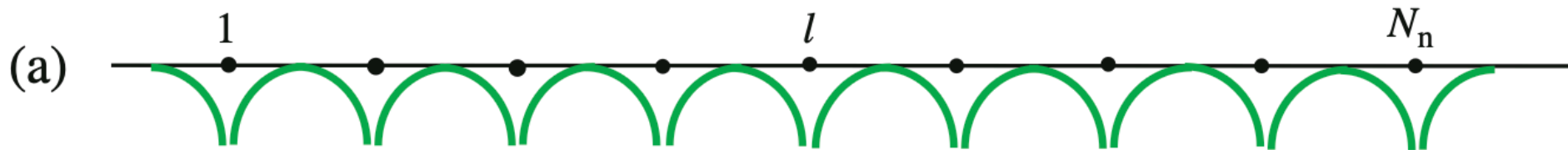
شکل ماتریسی معادله

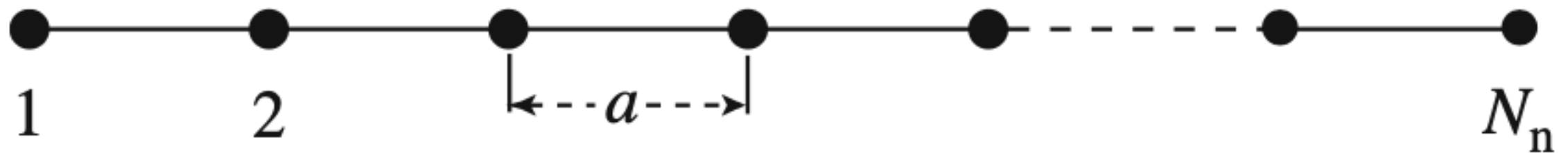
$$\left[\frac{\mathbf{p}^2}{2m_0} + V_{\text{at}}(\mathbf{r}) \right] \chi_n(\mathbf{r}) = E_n \chi_n(\mathbf{r}) .$$

شکل ماتریسی معادله
شرودینگر تک ذره ای
برای زنجیر تک ذره ای

$$-\sum_{l=1}^{N_n} t_{n,l} a_{k,l} = (E_k - E_v) a_{k,n}$$

$$-t_{n,l} = \langle \mathbf{R}_n | V_l(\mathbf{r}) | \mathbf{R}_l \rangle$$





$$-\sum_{l=1}^{N_n/2-1} t_l (a_{k,n+l} + a_{k,n-l}) = (E_k - E_v + t_0) a_{k,n}$$

$$\psi_k(x) = e^{ikx} u_k(x), \quad \text{with } u_k(x+a) = u_k(x)$$

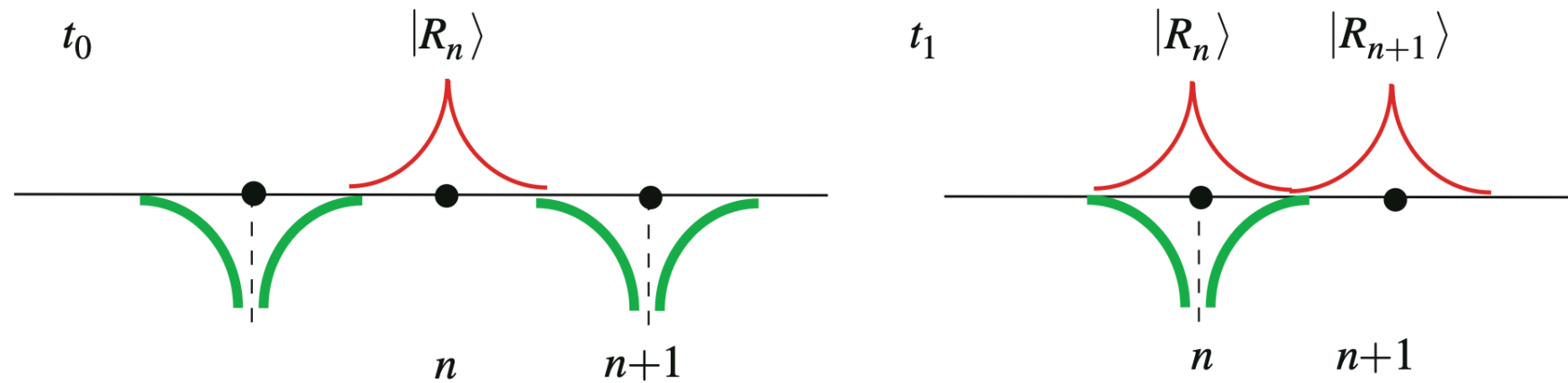
استفاده از توابع بلوخ و شرط مرزی تناوبی

$$k = \frac{2\pi m}{N_n a}, \quad m \text{ integer}$$

$$a_{k,n} = e^{ikR_n} = e^{ikna}$$

تقریب نزدیک ترین همسایه

$$t_n = 0 \quad \text{if } |n| > 1 .$$



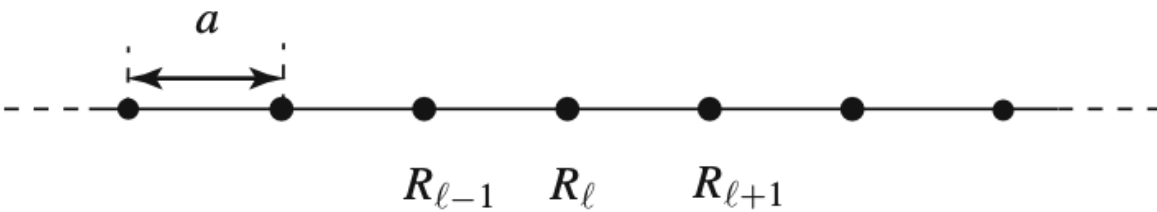
$$-t_1(a_{k,n+1} + a_{k,n-1}) = (E_k - E_v + t_0)a_{k,n} .$$

$$a_{k,n} = e^{ikR_n} = e^{ikna}$$

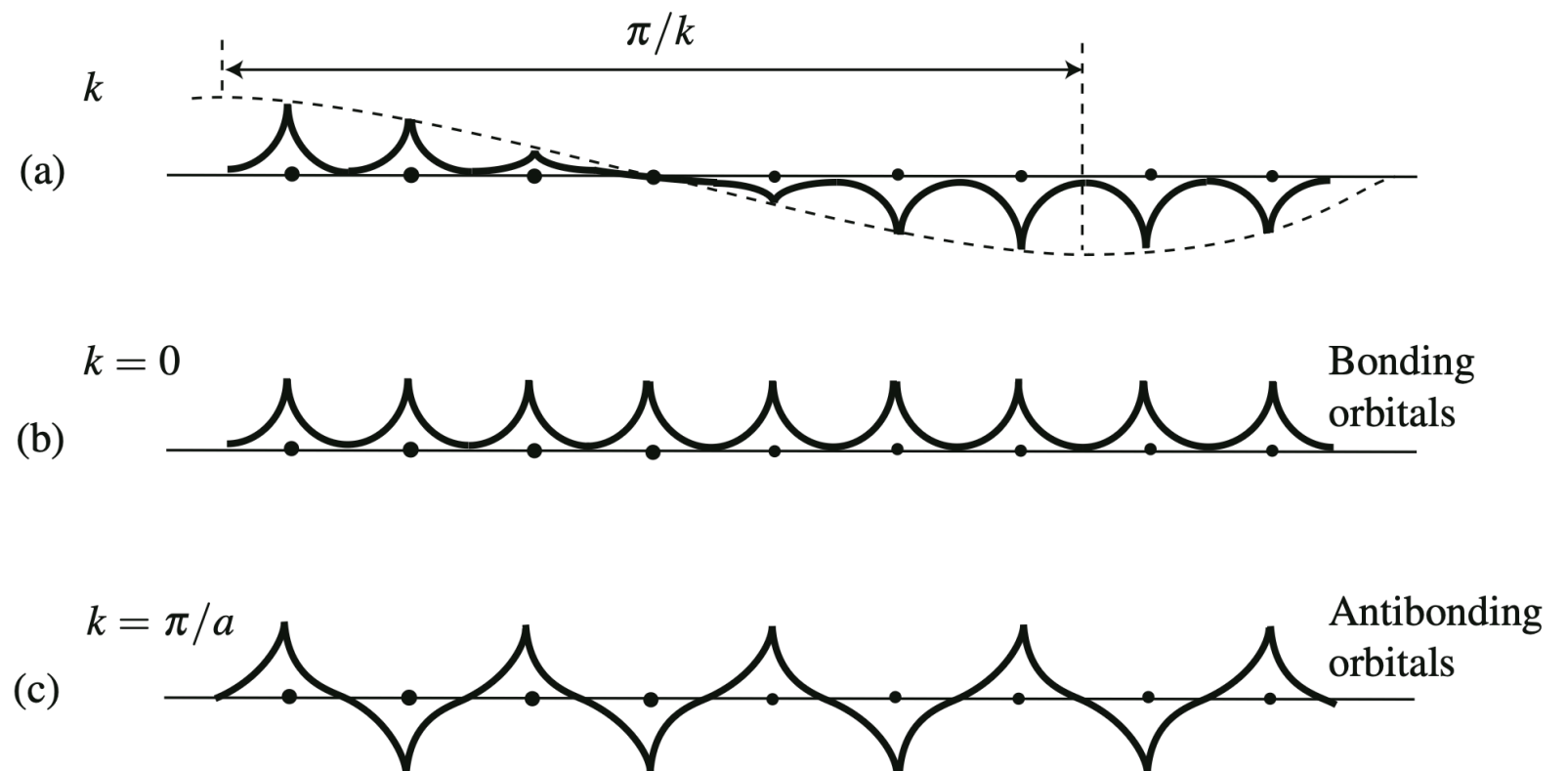
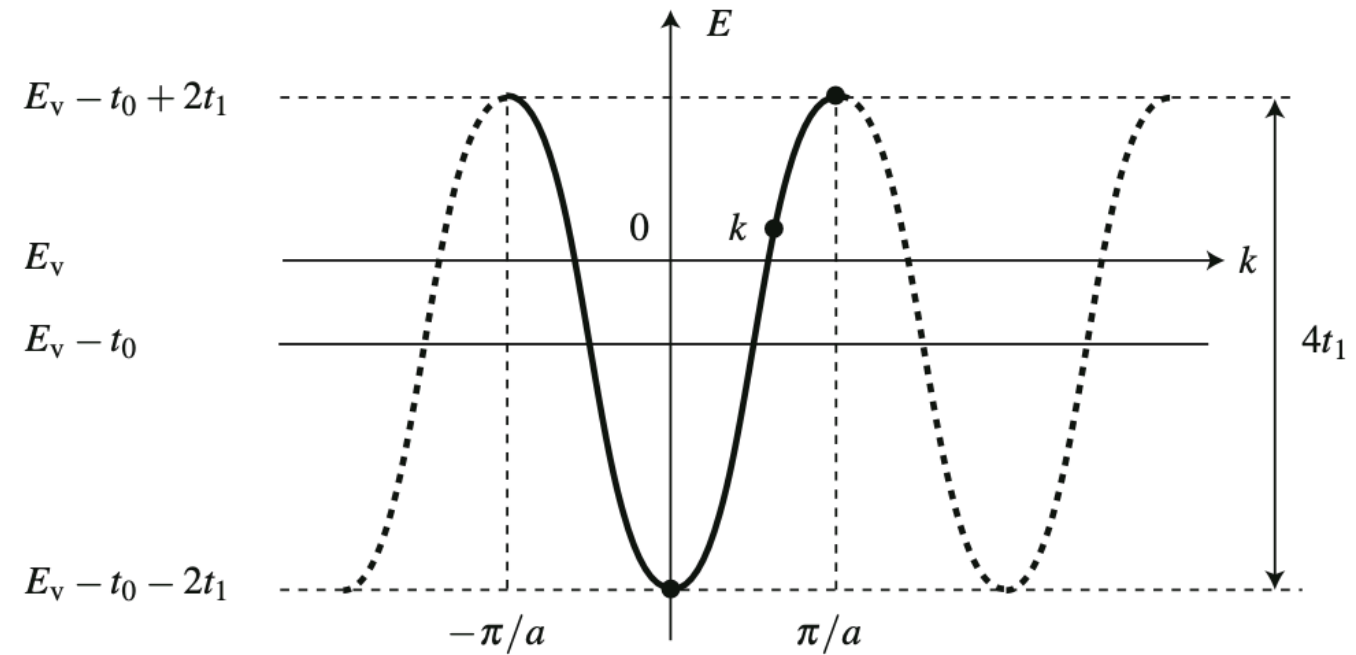
$$E_k = E_v - t_0 - 2t_1 \cos ka$$

$$|\psi_k\rangle = \frac{1}{\sqrt{N_n}} \sum_{l=1}^{N_n} e^{ikla} |R_l\rangle$$

Band Structure

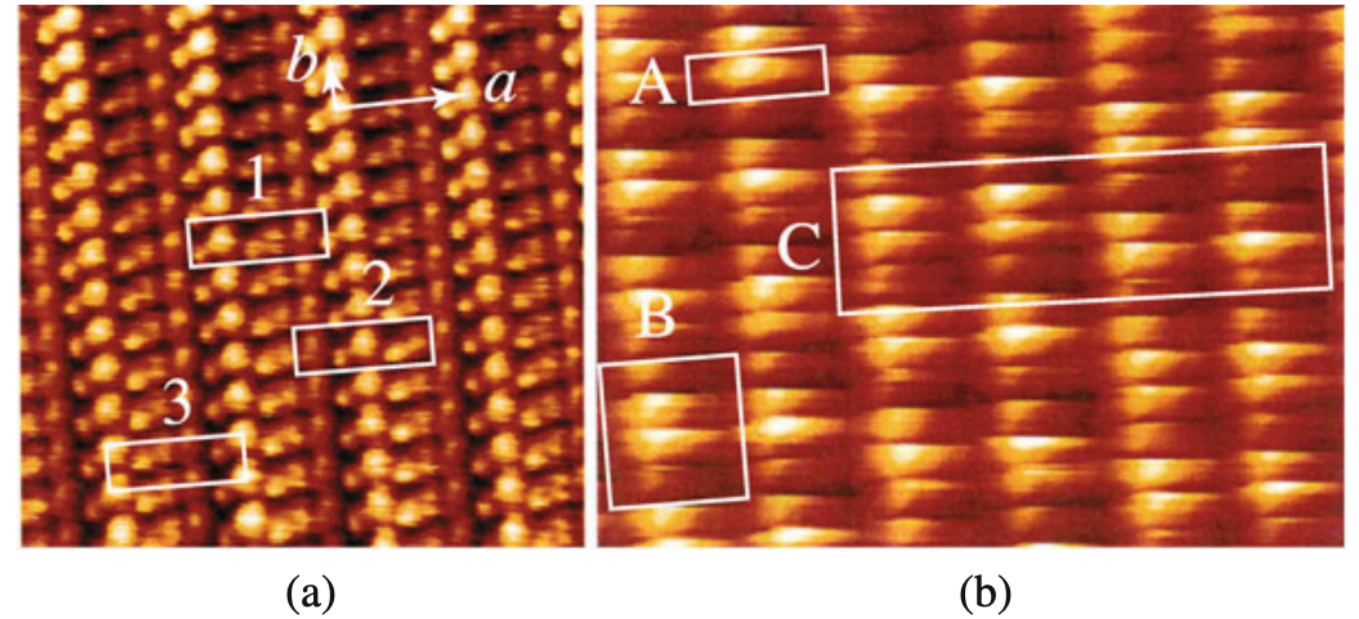
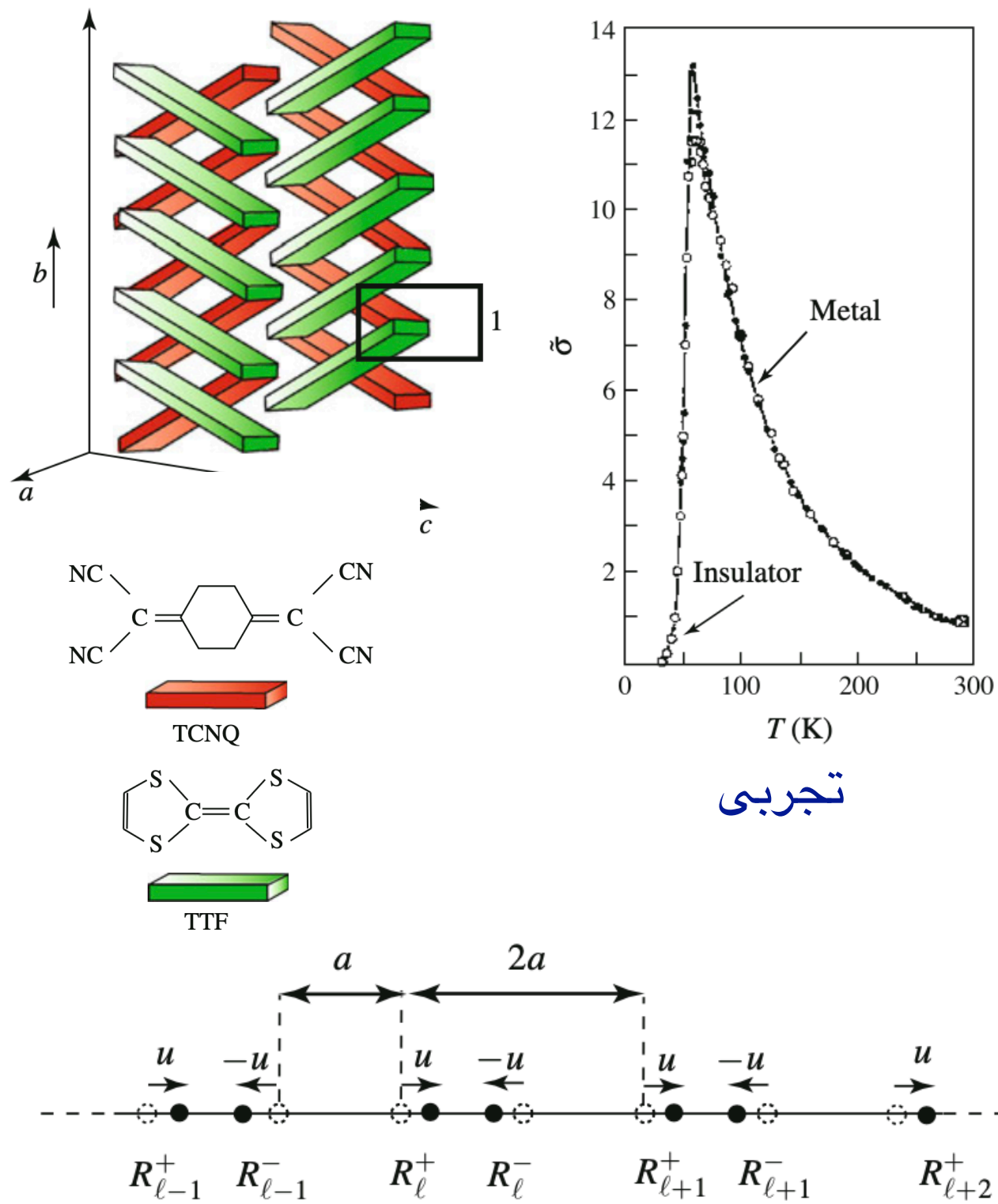


$$E_k = E_v - t_0 - 2t_1 \cos ka$$

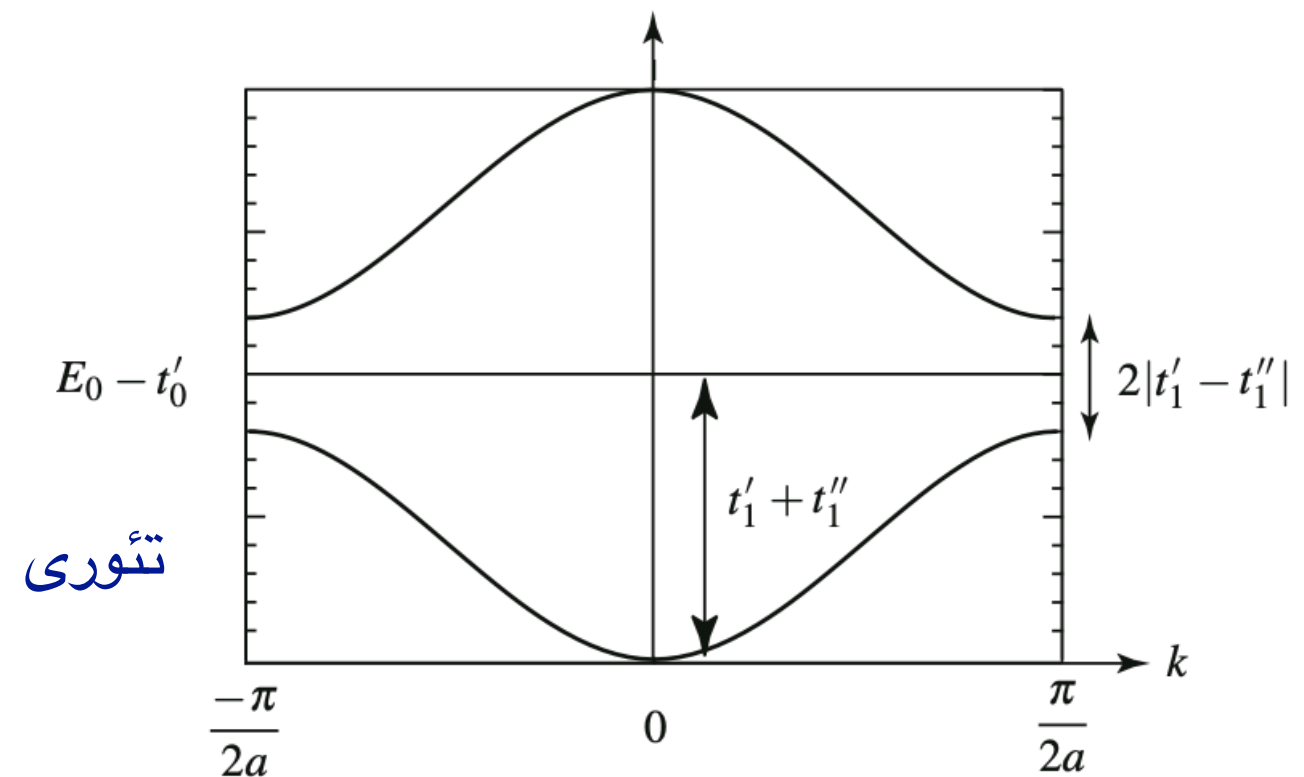


$$|\psi_k\rangle = \frac{1}{\sqrt{N_n}} \sum_{l=1}^{N_n} e^{ikla} |R_l\rangle$$

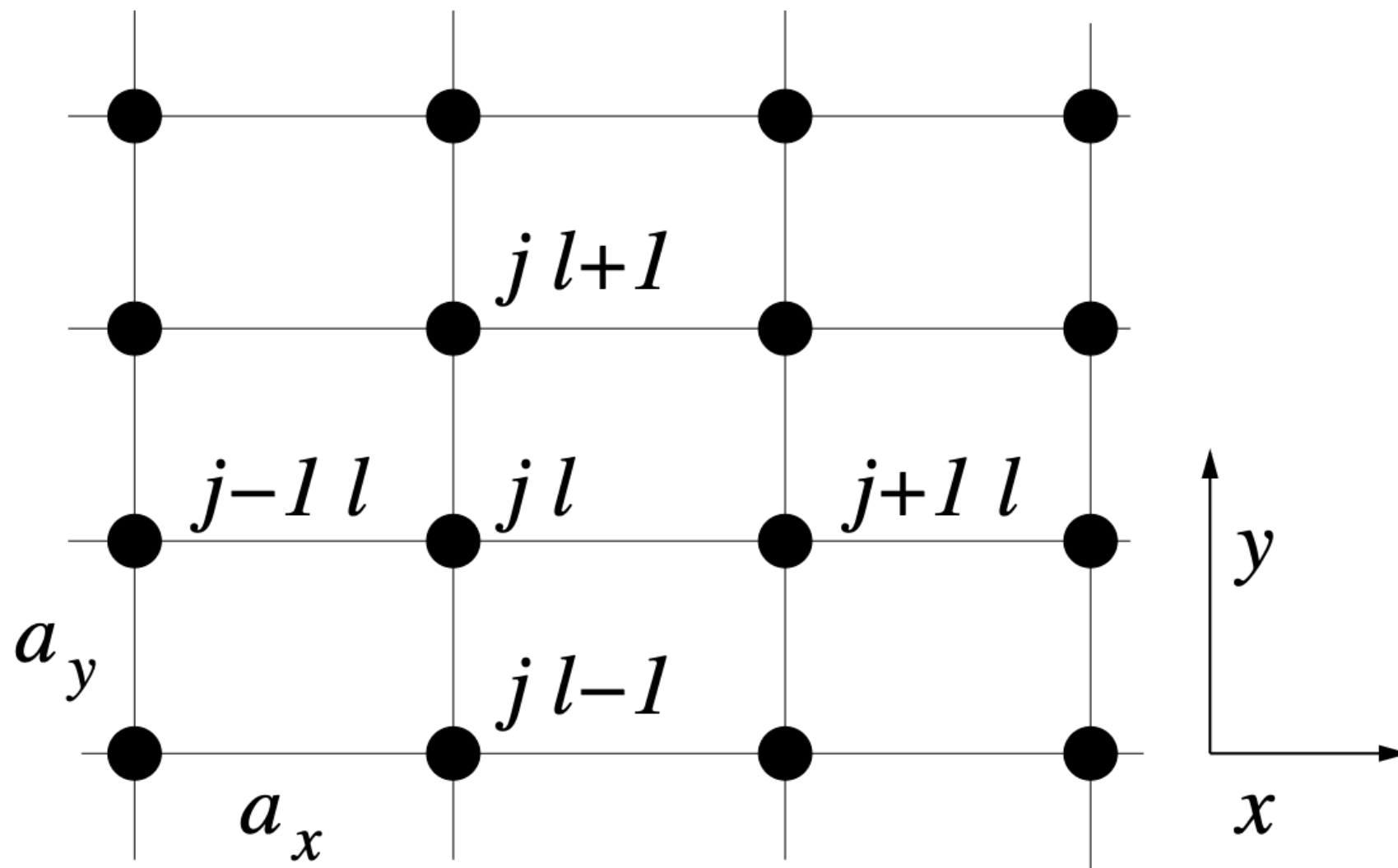
بلور TTF-TCNQ



تجربی

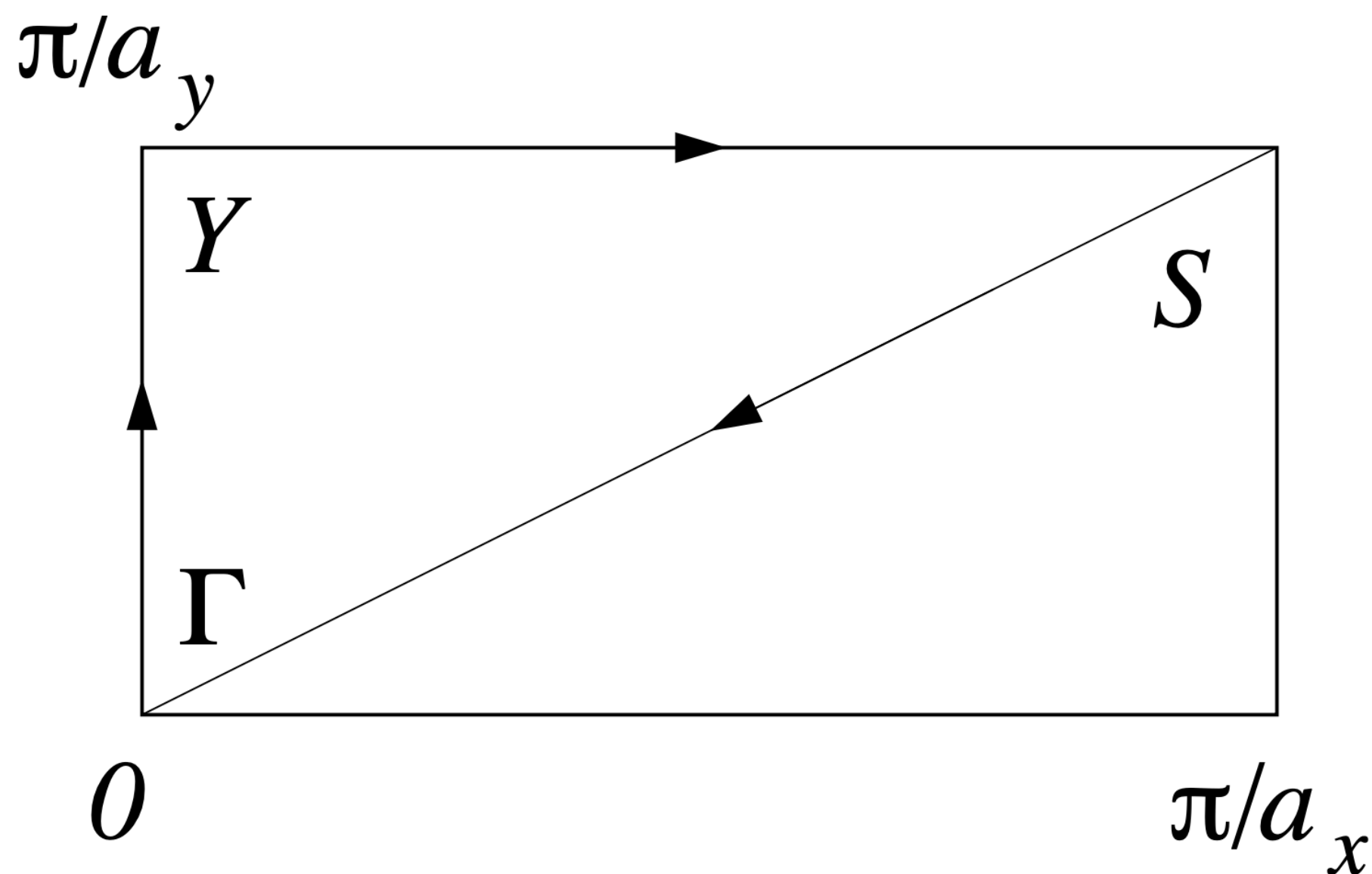


تئوری



$$E = \epsilon_0 + 2\gamma_x \cos(k_x a_x) + 2\gamma_y \cos(k_y a_y)$$

$$(k_x, k_y) = (0, 0) \rightarrow (0, \pi/a_y) \rightarrow (\pi/a_x, \pi/a_y) \rightarrow (0, 0)$$

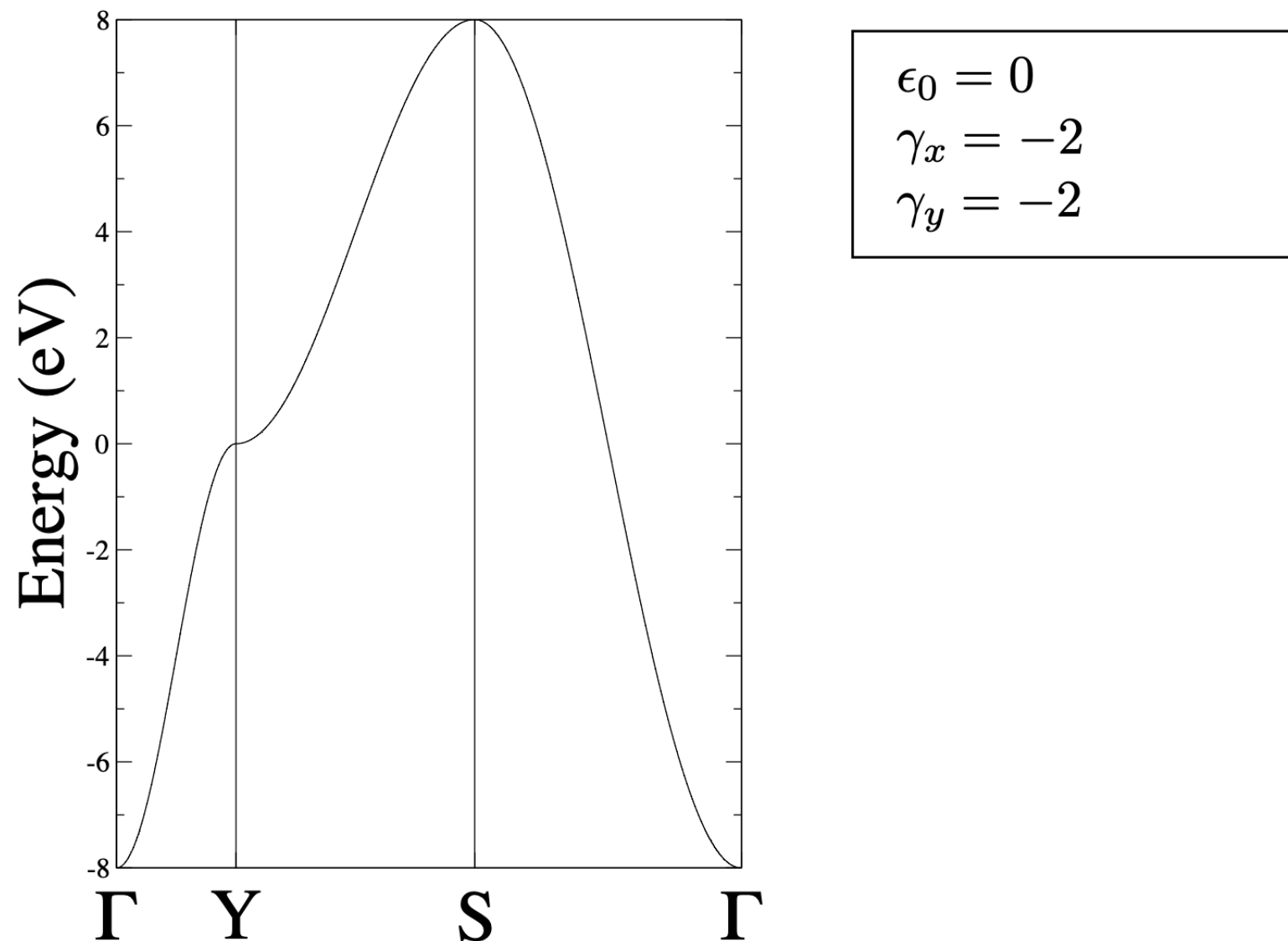


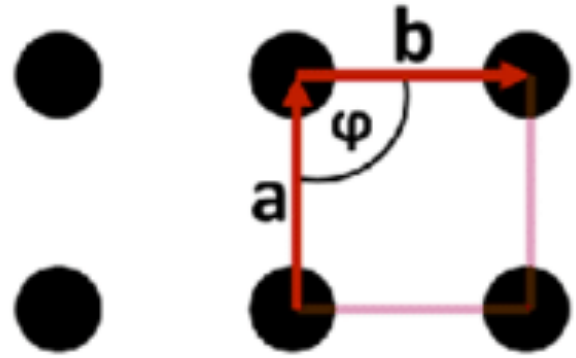
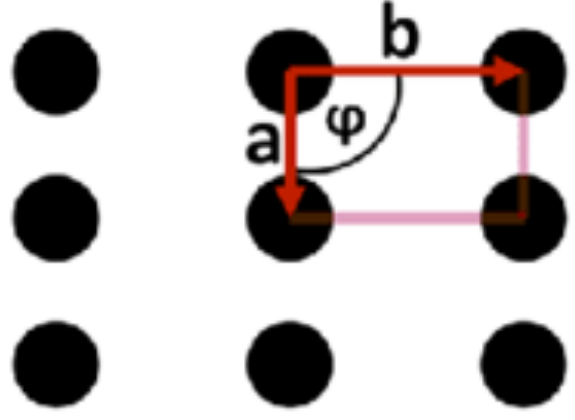
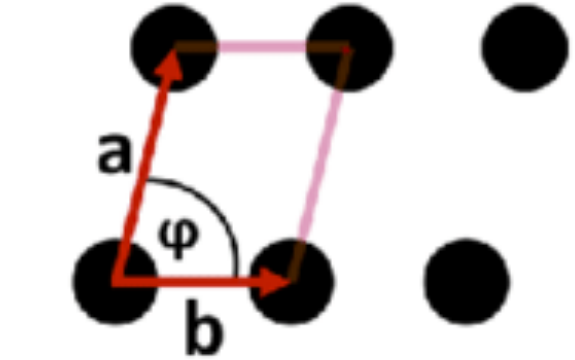
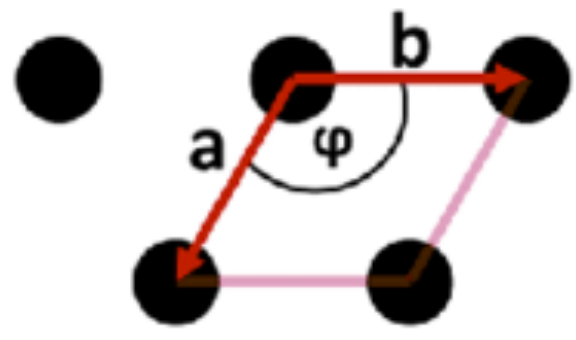
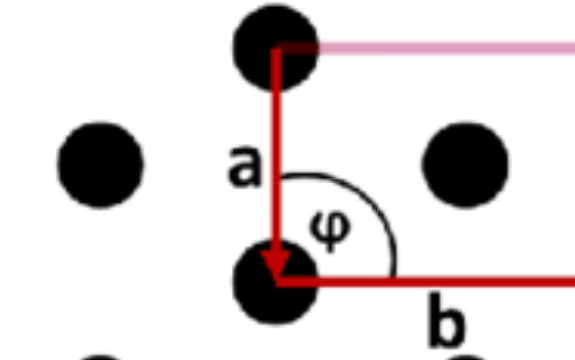
ساختار نواری - مسیر بین نقاط پرتقارن

$$a_y = 2a_x = 2a_0 \quad E = \epsilon_0 + 2\gamma_x \cos(k_x a_0) + 2\gamma_y \cos(2k_y a_0)$$

$$(k_x, k_y) = (0, 0) \rightarrow (0, \pi/a_y) \rightarrow (\pi/a_x, \pi/a_y) \rightarrow (0, 0)$$

$$(k_x, k_y) = \Gamma \rightarrow Y \rightarrow S \rightarrow \Gamma$$



(a) Linear 	(b) Square 	(c) Rectangular 
a	$a = b , \varphi = 90^\circ$	$a \neq b , \varphi = 90^\circ$
(d) Oblique 	(e) Hexagonal 	(f) Centered Rectangular 
$a \neq b , \varphi \neq 90^\circ$	$a = b , \varphi = 120^\circ$	$a \neq b , \varphi = 90^\circ$

Quasicrystals

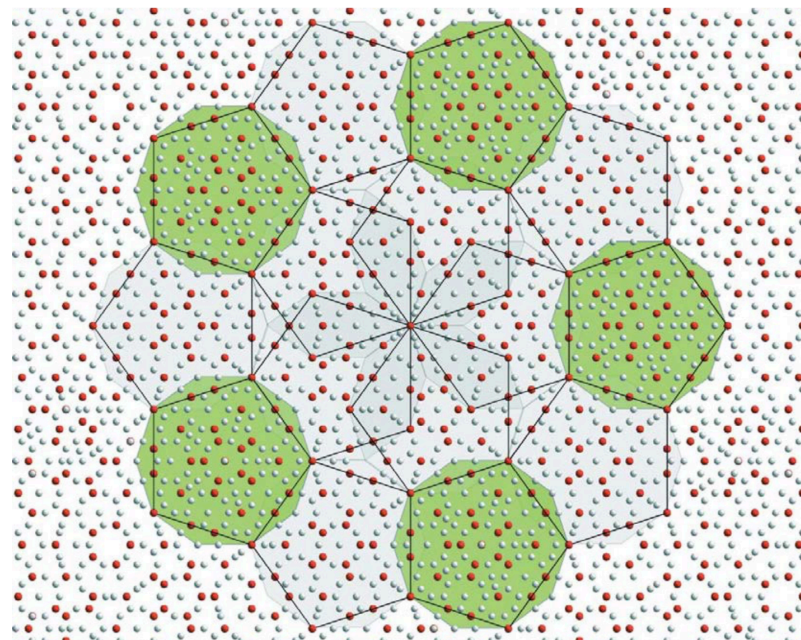
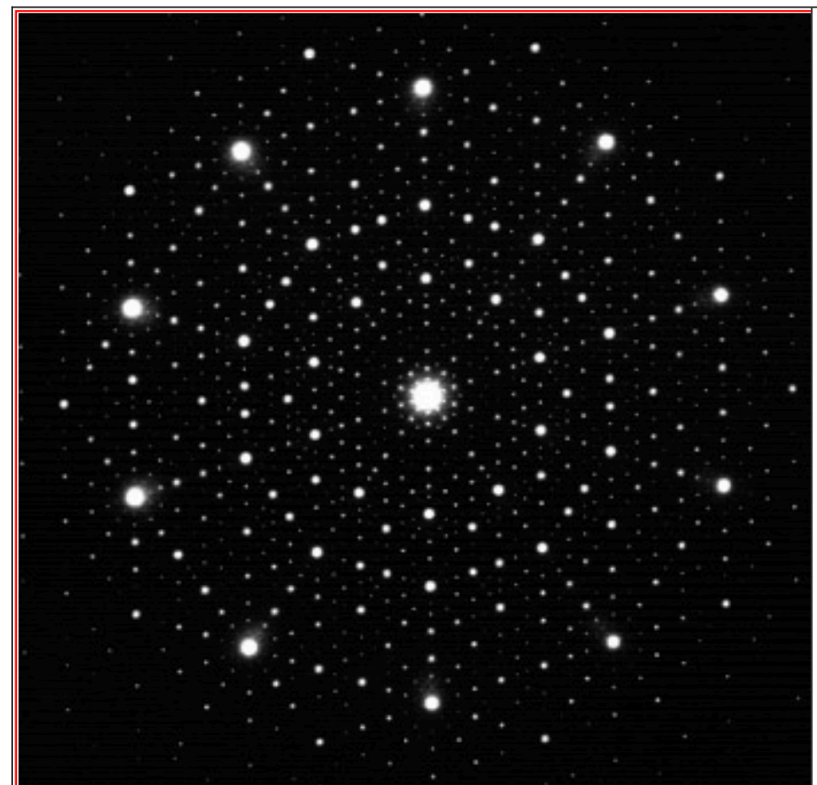
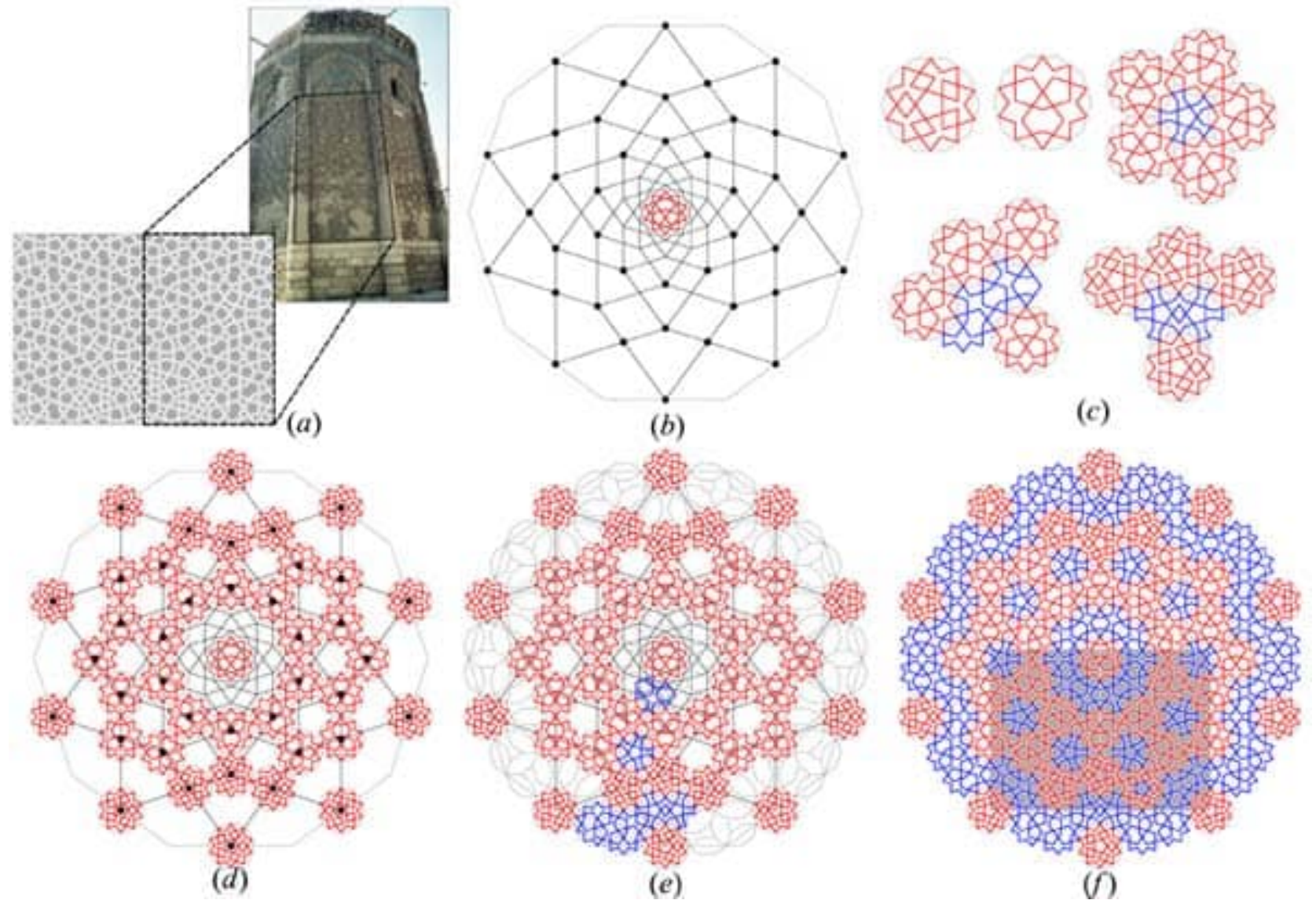


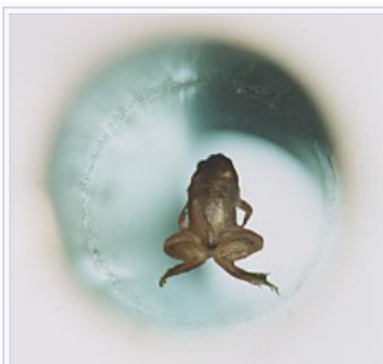
Figure 8. Section perpendicular to the decagonal axis of Al-Co-Ni³⁶.



The Nobel Prize in Chemistry 2011 is awarded to **Dan Shechtman**



Quasi-periodic pattern at the Gunbad-I Kabud tomb tower in Maragh



The 2000 Ig Nobel Prize in physics was awarded to [Andre Geim](#), Radboud University Nijmegen, and [Michael Berry](#), University of Bristol, UK, for the [magnetic levitation](#) of a live frog. Geim was awarded an actual Nobel Prize in Physics in 2010.^[1]

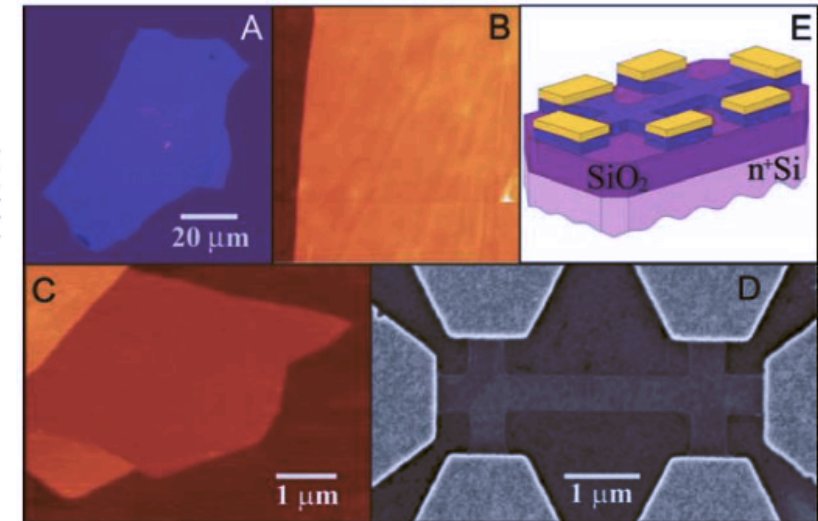


Electric Field Effect in Atomically Thin Carbon Films

K. S. Novoselov,¹ A. K. Geim,^{1*} S. V. Morozov,² D. Jiang,¹ Y. Zhang,¹ S. V. Dubonos,² I. V. Grigorieva,¹ A. A. Firsov²

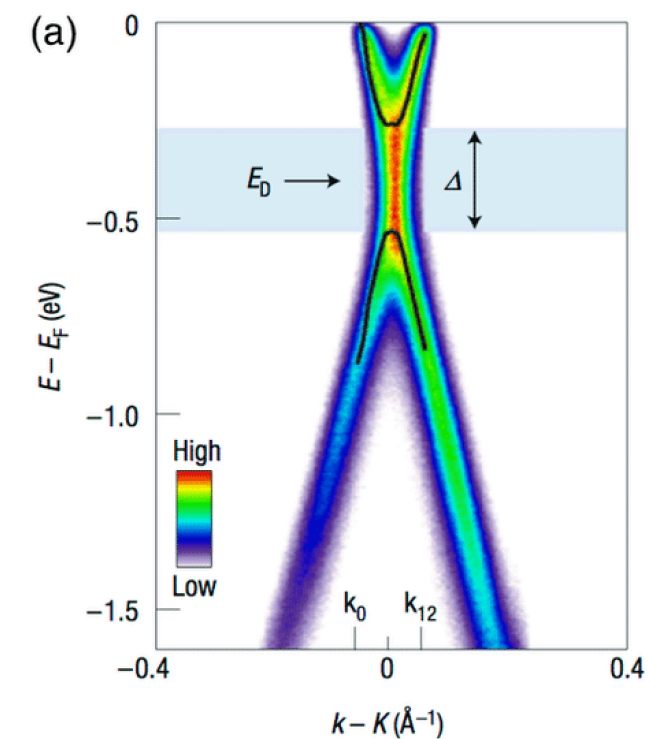
We describe monocrystalline graphitic films, which are a few atoms thick but are nonetheless stable under ambient conditions, metallic, and of remarkably high quality. The films are found to be a two-dimensional semimetal with a tiny overlap between valence and conduction bands, and they exhibit a strong ambipolar electric field effect such that electrons and holes in concentrations up to 10^{13} per square centimeter and with room-temperature mobilities of $\sim 10,000$ square centimeters per volt-second can be induced by applying gate voltage.

22 OCTOBER 2004 VOL 306 SCIENCE www.sciencemag.org

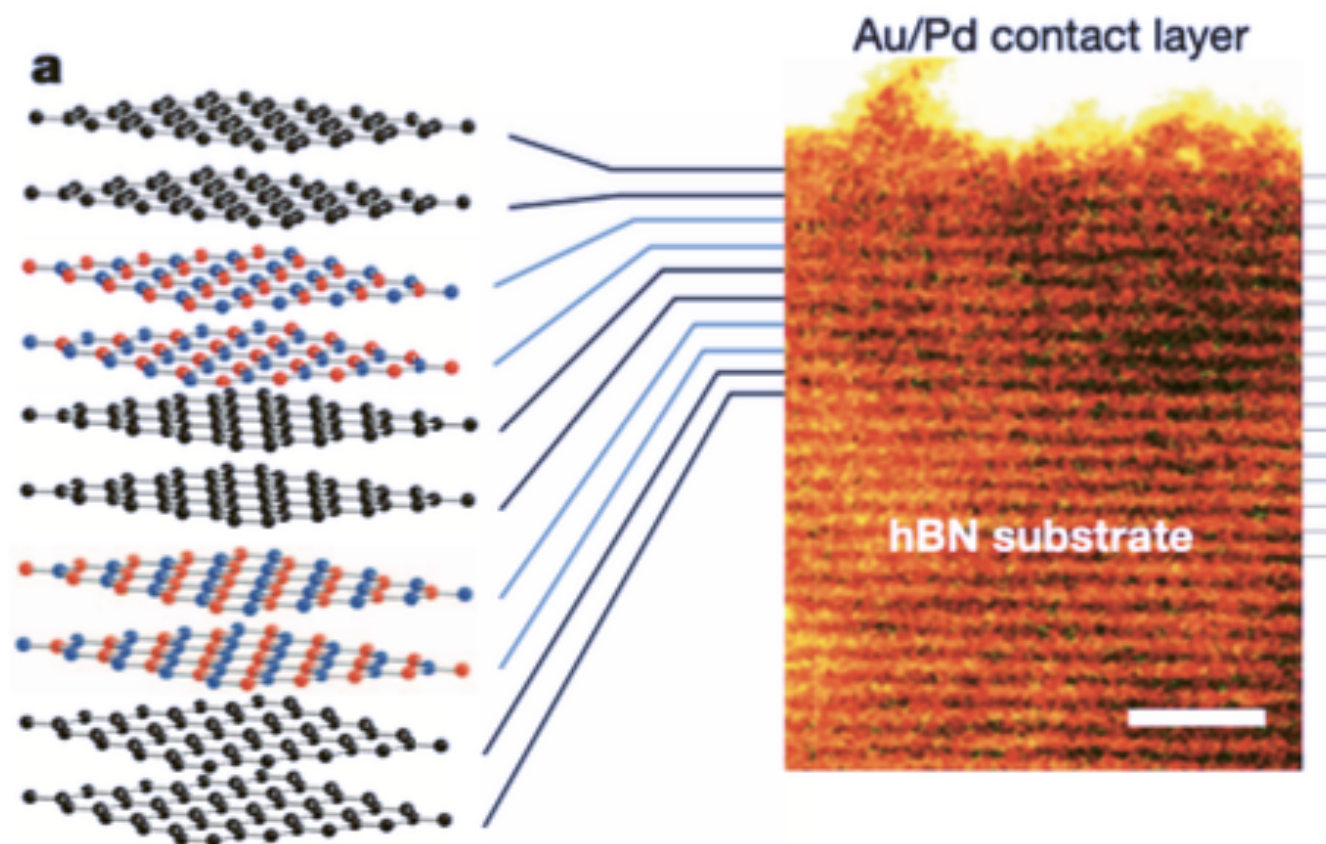
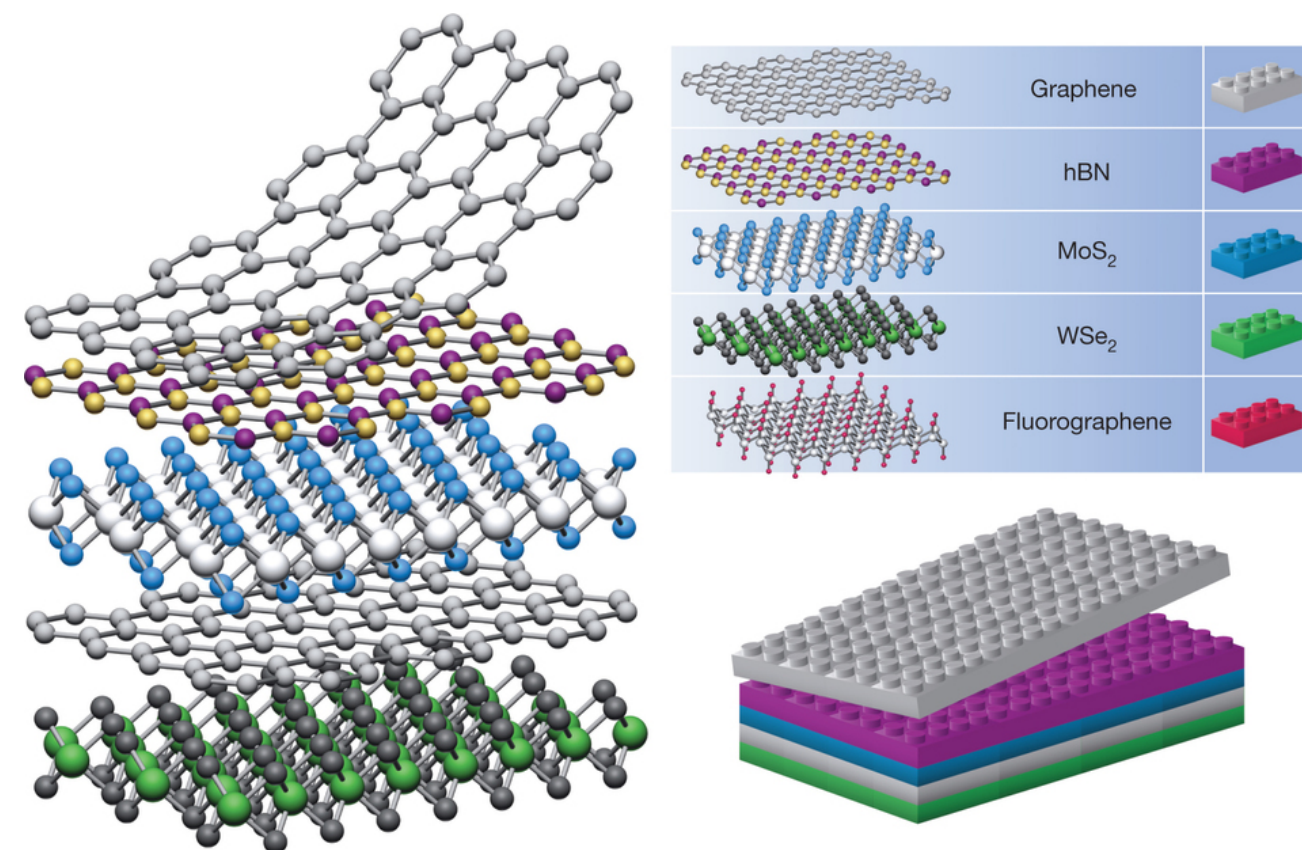


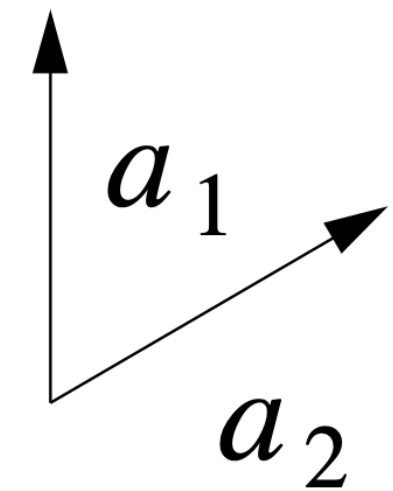
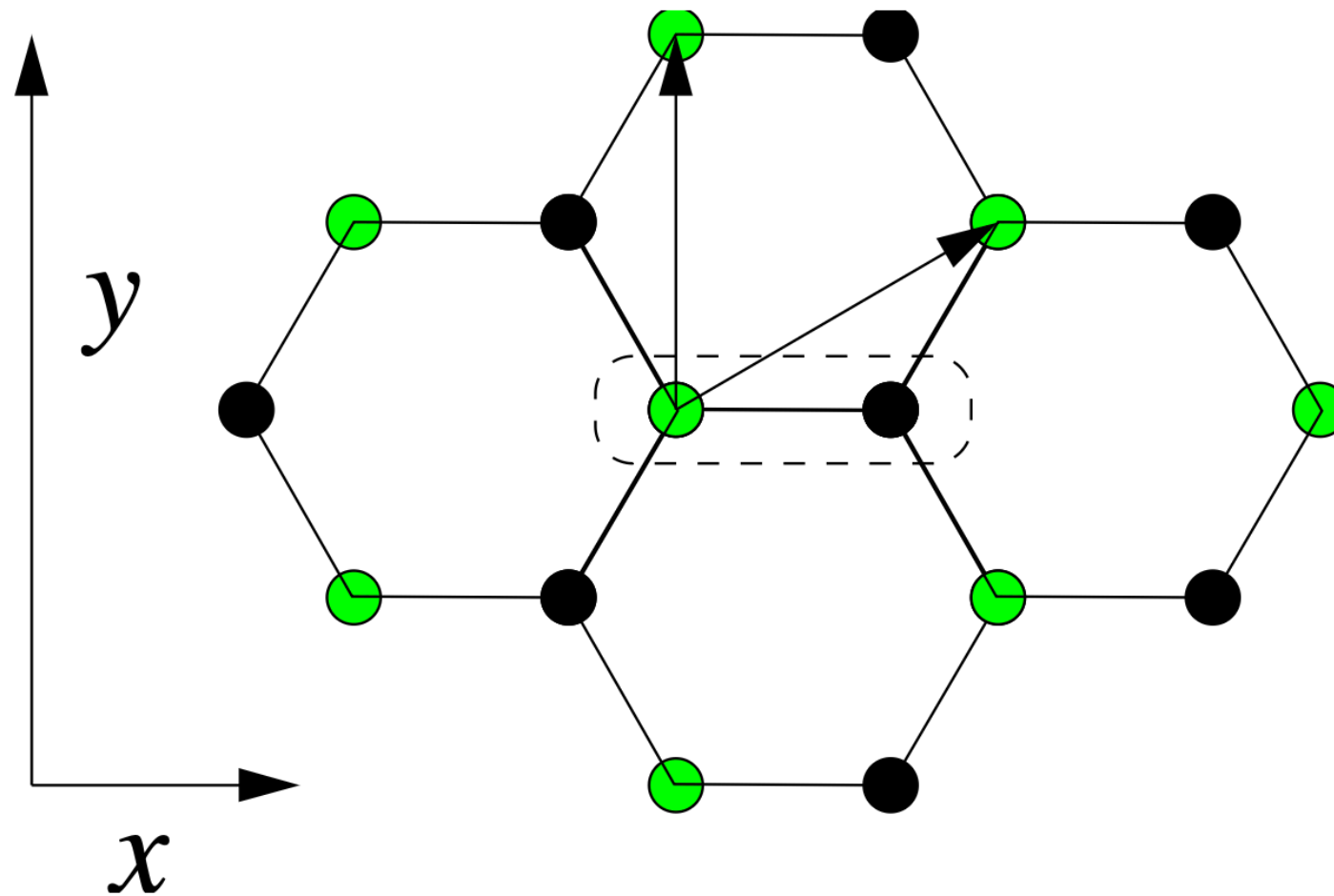
Graphene films.

- (A) Photograph (in normal white light) of a relatively large multilayer graphene flake with thickness 3 nm on top of an oxidized Si wafer.
- (B) Atomic force microscope (AFM) image of 2 μm by 2 μm area of this flake near its edge. Colors: dark brown, SiO_2 surface; orange, 3 nm height above the SiO_2 surface.
- (C) AFM image of single-layer graphene. Colors: dark brown, SiO_2 surface; brown-red (central area), 0.8 nm height; yellow-brown (bottom left), 1.2 nm; orange (top left), 2.5 nm. Notice the folded part of the film near the bottom, which exhibits a differential height of 0.4 nm.
- (D) Scanning electron microscope image of one of our experimental devices prepared from FLG.
- (E) Schematic view of the device in (D).



ساختارهای ناهمگون

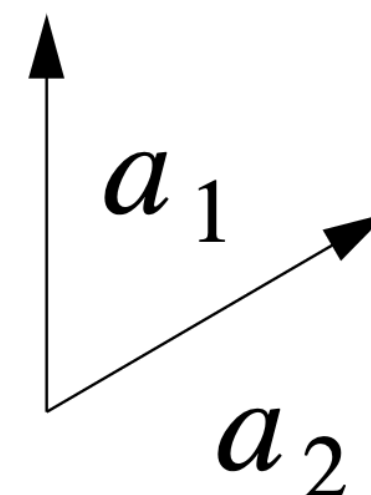
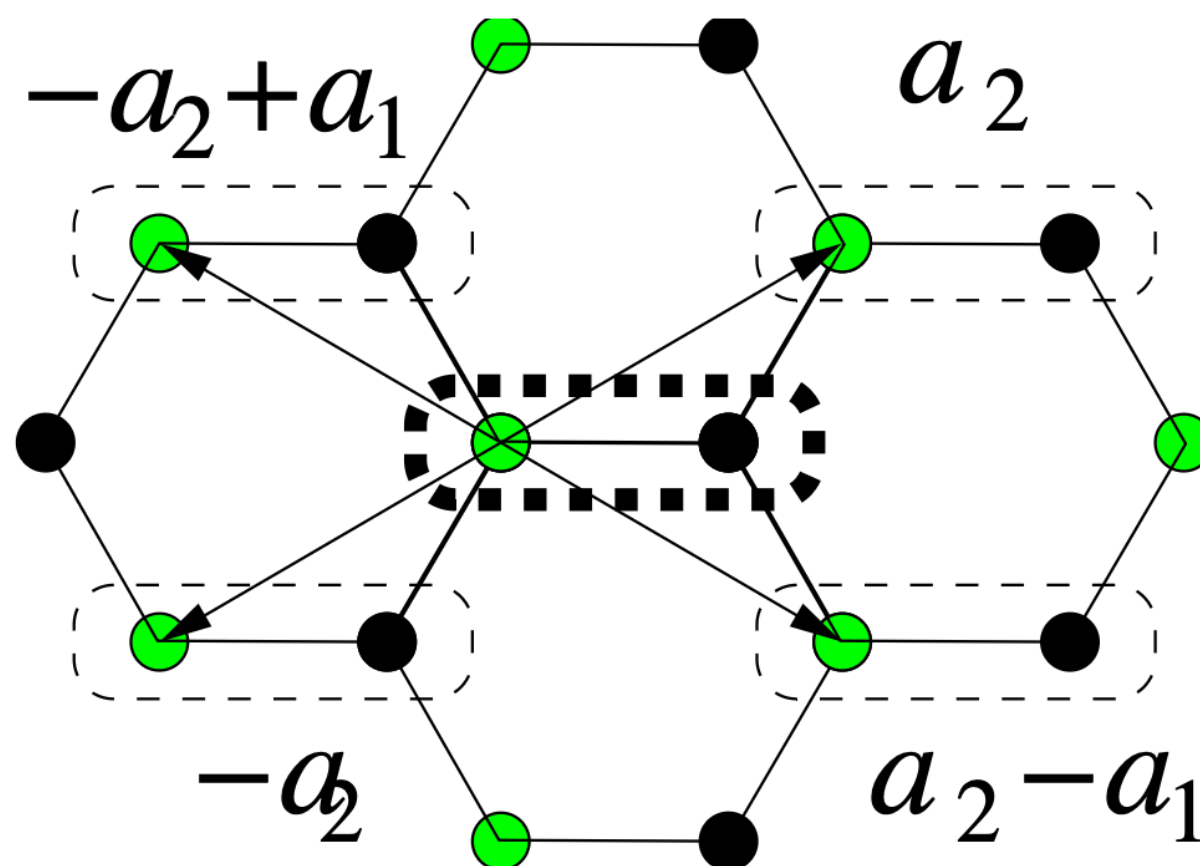


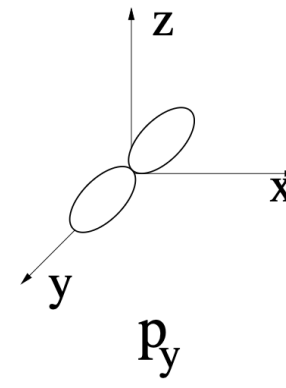
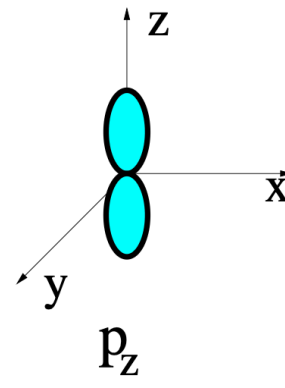
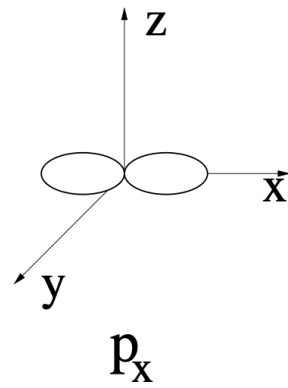
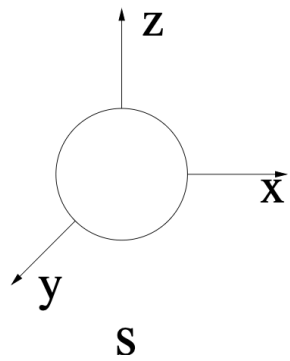
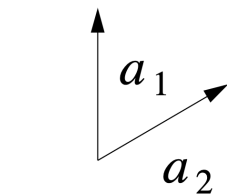
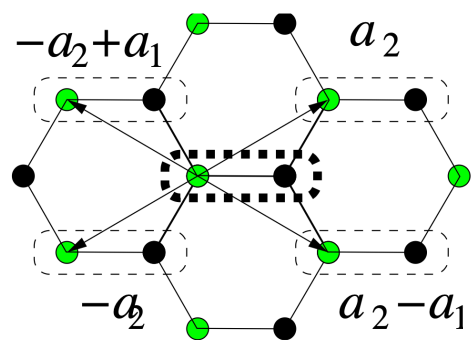


$$\begin{cases} \vec{a}_1 = a_0 \hat{y} \\ \vec{a}_2 = a_0 \left(\frac{\sqrt{3}}{2} \hat{x} + \frac{1}{2} \hat{y} \right) \end{cases}$$

$$|\psi_{\vec{k}}\rangle = \frac{1}{N^{1/2}} \sum_{\vec{R}} \sum_{n=1}^2 e^{i\vec{k} \cdot \vec{R}} A_{\vec{n}}^{\vec{k}} |\vec{R} n\rangle$$

$$E(\vec{k}) A_{\vec{n}'}^{\vec{k}} = \sum_{\vec{R}} \sum_n^2 e^{i\vec{k} \cdot (\vec{R} - \vec{R}')} A_n^{\vec{k}} \langle \vec{R}' n' | H | \vec{R} n \rangle$$



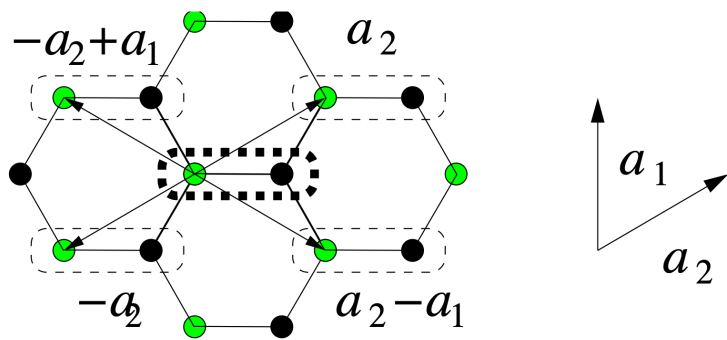


$$E(\vec{k}) A_{n'}^{\vec{k}} = \sum_{\vec{R}} \sum_n^2 e^{i\vec{k} \cdot (\vec{R} - \vec{R}')} A_n^{\vec{k}} \langle \vec{R}' n' | H | \vec{R} n \rangle$$

On-site energy: coupling with the primitive cell

$$\langle \vec{R}' n' | H | \vec{R}' n \rangle = \begin{pmatrix} \epsilon_p & \gamma_{pp\pi} \\ \gamma_{pp\pi} & \epsilon_p \end{pmatrix}$$

The phase factor is $e^{i\vec{k} \cdot (\vec{R}' - \vec{R}')} = 1$



$$E(\vec{k}) A_{n'}^{\vec{k}} = \sum_{\vec{R}} \sum_n^2 e^{i\vec{k} \cdot (\vec{R} - \vec{R}')} A_n^{\vec{k}} \langle \vec{R}' n' | H | \vec{R} n \rangle$$

Off-diagonal terms: coupling with other cells

1. Cell $\vec{a}_2$

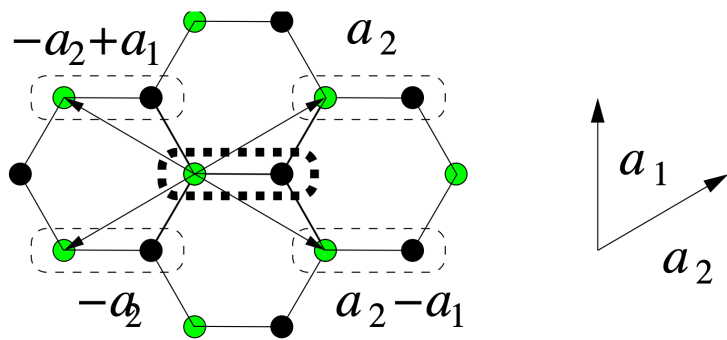
$$\langle \vec{R}' n' | H | \vec{R}' + \vec{a}_2 n \rangle = \begin{pmatrix} 0 & 0 \\ \gamma_{pp\pi} & 0 \end{pmatrix}$$

The phase factor is $e^{i\vec{k} \cdot (\vec{R}' + \vec{a}_2 - \vec{R}')} = e^{i\vec{k} \cdot \vec{a}_2}$

2. Cell $\vec{a}_2 - \vec{a}_1$

$$\langle \vec{R}' n' | H | \vec{R}' + \vec{a}_2 - \vec{a}_1 n \rangle = \begin{pmatrix} 0 & 0 \\ \gamma_{pp\pi} & 0 \end{pmatrix}$$

The phase factor is $e^{i\vec{k} \cdot (\vec{R}' + \vec{a}_2 - \vec{a}_1 - \vec{R}')} = e^{i\vec{k} \cdot (\vec{a}_2 - \vec{a}_1)}$



$$E(\vec{k}) A_{n'}^{\vec{k}} = \sum_{\vec{R}} \sum_n^2 e^{i\vec{k} \cdot (\vec{R} - \vec{R}')} A_n^{\vec{k}} \langle \vec{R}' n' | H | \vec{R} n \rangle$$

Off-diagonal terms: coupling with other cells

3. Cell $-\vec{a}_2$

$$\langle \vec{R}' n' | H | \vec{R}' - \vec{a}_2 n \rangle = \begin{pmatrix} 0 & \gamma_{pp\pi} \\ 0 & 0 \end{pmatrix}$$

The phase factor is $e^{i\vec{k} \cdot (\vec{R}' - \vec{a}_2 - \vec{R}')} = e^{-i\vec{k} \cdot \vec{a}_2}$

4. Cell $-\vec{a}_2 + \vec{a}_1$

$$\langle \vec{R}' n' | H | \vec{R}' - \vec{a}_2 + \vec{a}_1 n \rangle = \begin{pmatrix} 0 & \gamma_{pp\pi} \\ 0 & 0 \end{pmatrix}$$

The phase factor is $e^{i\vec{k} \cdot (\vec{R}' - \vec{a}_2 + \vec{a}_1 - \vec{R}')} = e^{-i\vec{k} \cdot (\vec{a}_2 - \vec{a}_1)}$

$$E(\vec{k}) A_{n'}^{\vec{k}} = \sum_{\vec{R}} \sum_n^2 e^{i\vec{k} \cdot (\vec{R} - \vec{R}')} A_n^{\vec{k}} \langle \vec{R}' n' | H | \vec{R} n \rangle$$

$$E(\vec{k}) \Psi_{\vec{k}} = \begin{pmatrix} \epsilon_p & \gamma_{pp\pi} f(\vec{k}) \\ \gamma_{pp\pi} f(\vec{k})^* & \epsilon_p \end{pmatrix} \Psi_{\vec{k}}$$

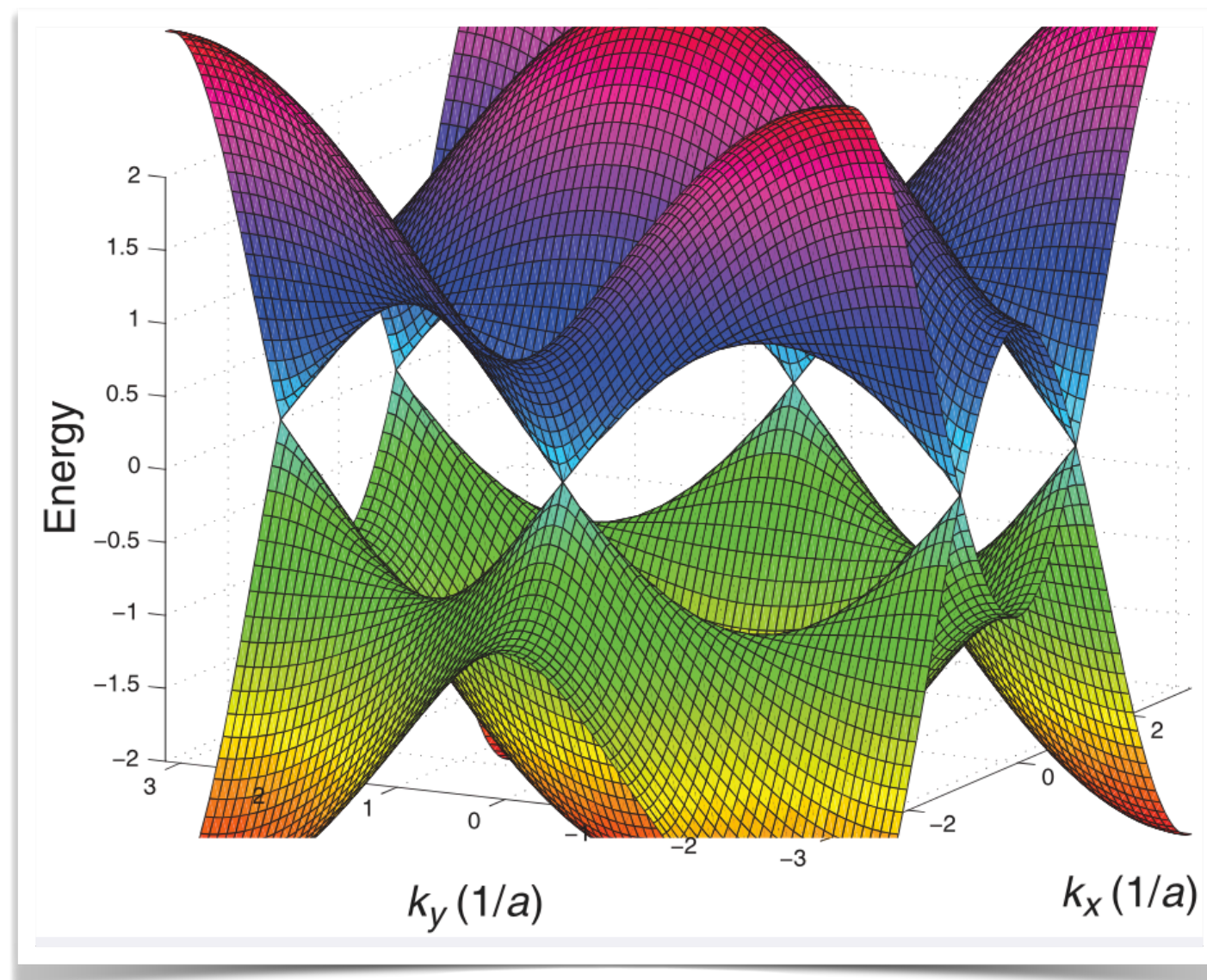
$$f(\vec{k}) = 1 + e^{-i\vec{k} \cdot \vec{a}_2} + e^{-i\vec{k} \cdot (\vec{a}_2 - \vec{a}_1)} = 1 + 2 e^{-ik_x \frac{\sqrt{3}}{2} a_0} \cos\left(\frac{k_y}{2} a_0\right)$$

$$\det \begin{pmatrix} \epsilon_p - E(\vec{k}) & \gamma_{pp\pi} f(\vec{k}) \\ \gamma_{pp\pi} f(\vec{k})^* & \epsilon_p - E(\vec{k}) \end{pmatrix} = 0$$

$$E(\vec{k}) = \epsilon_p \pm \gamma_{pp\pi} \sqrt{f(\vec{k}) f(\vec{k})^*}$$

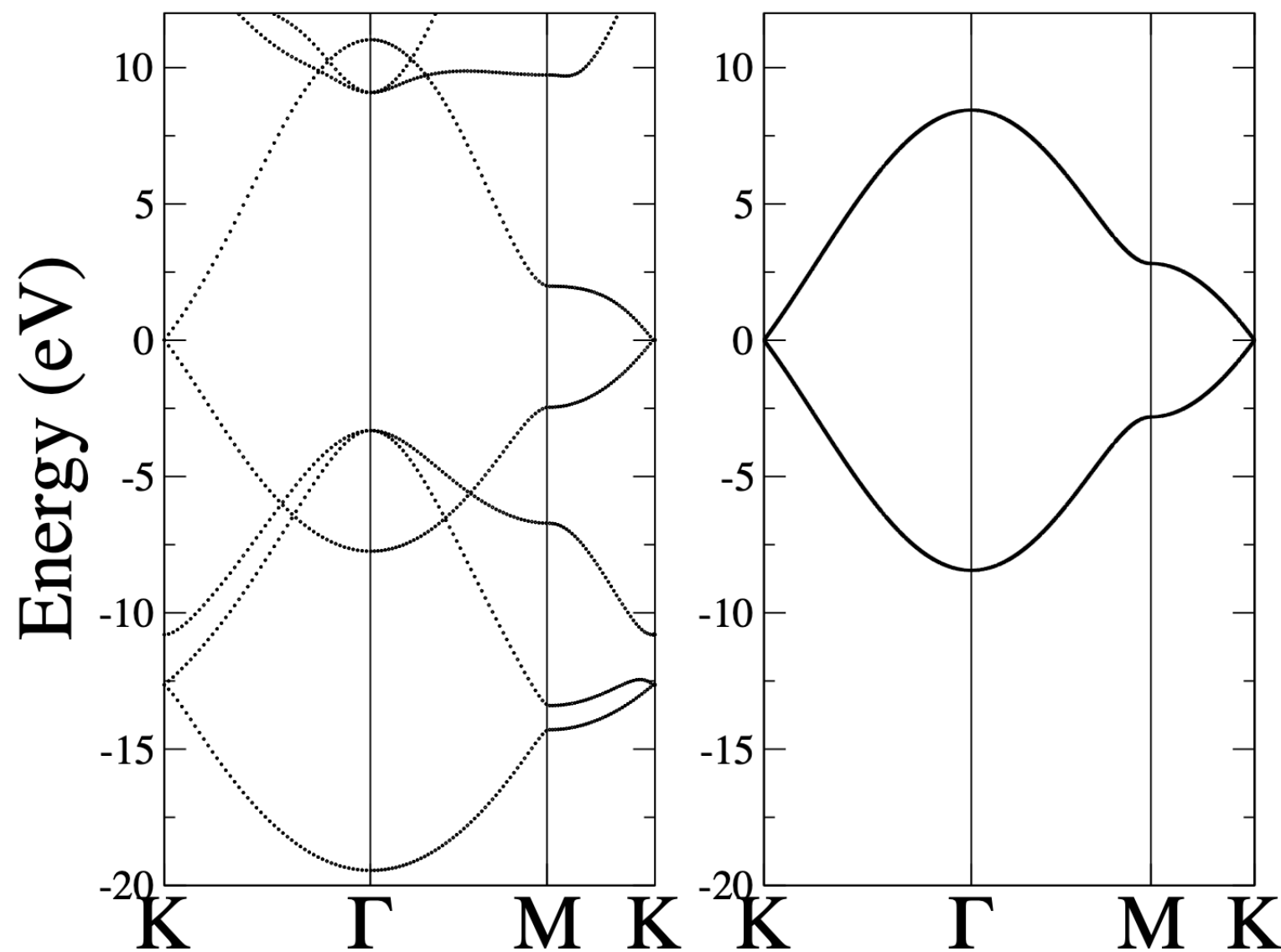
$$E(\vec{k}) = \epsilon_p \pm$$

$$\pm \gamma_{pp\pi} \sqrt{1 + 4 \cos^2 \left(\frac{k_y a_0}{2} \right) + 4 \cos \left(\frac{k_y a_0}{2} \right) \cos \left(\frac{\sqrt{3}}{2} k_x a_0 \right)}$$

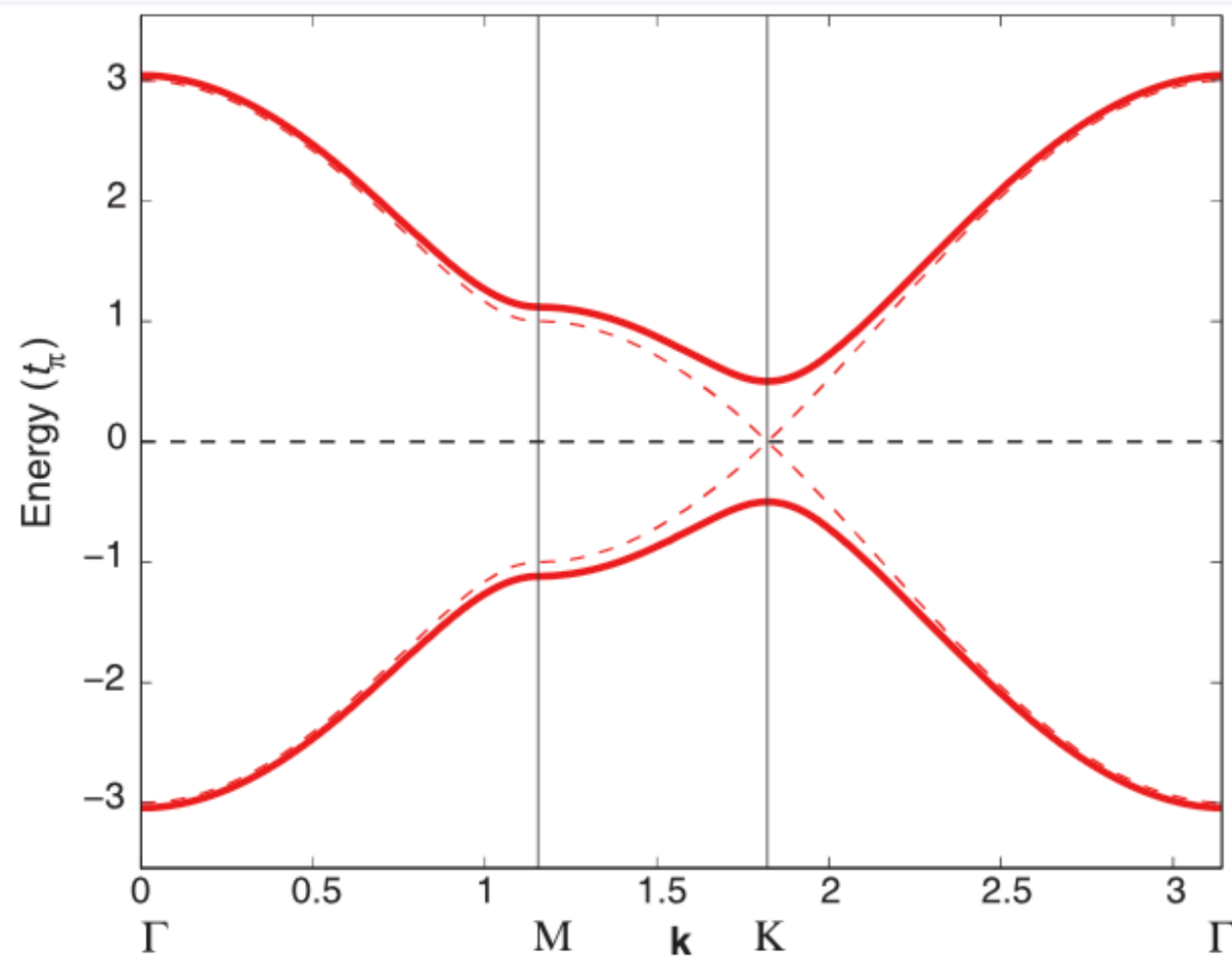
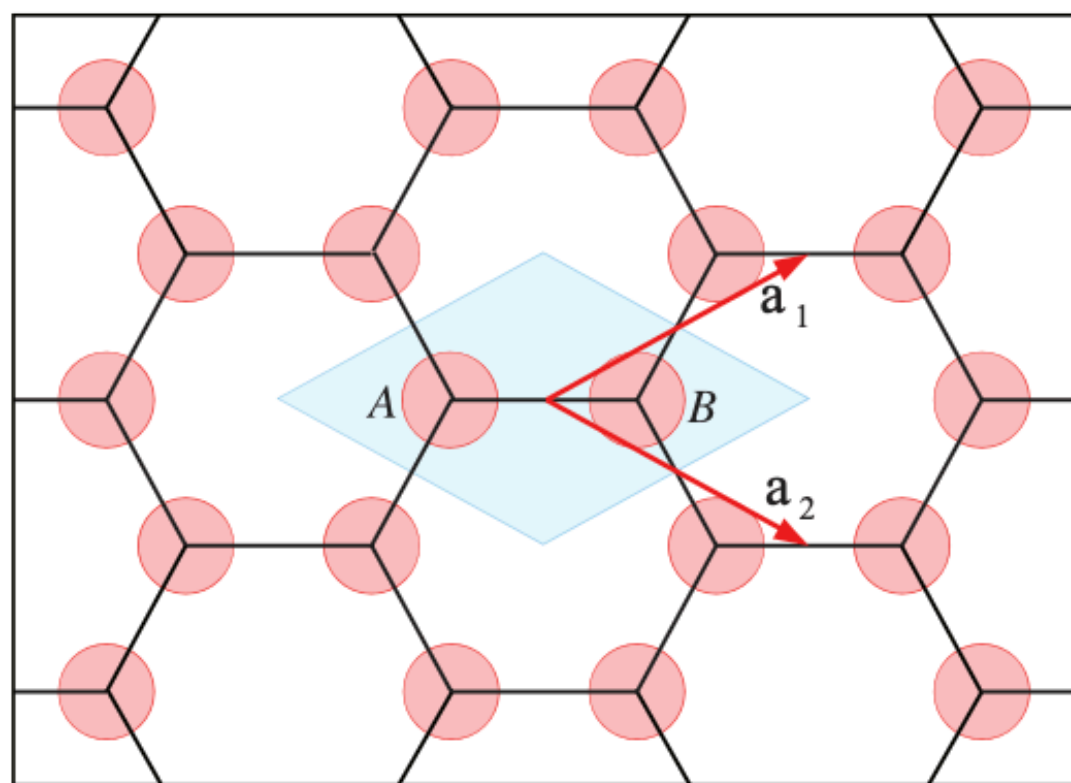


$$E(\vec{k}) = \epsilon_p \pm$$

$$\pm \gamma_{pp\pi} \sqrt{1 + 4 \cos^2 \left(\frac{k_y a_0}{2} \right) + 4 \cos \left(\frac{k_y a_0}{2} \right) \cos \left(\frac{\sqrt{3}}{2} k_x a_0 \right)}$$



پروژه : اثر شکست تقارن وارونی بر ساختار نواری



مراحل انجام پروژه (تیم ۳ نفره)

۱- مطالعه مقاله

۲- محاسبه ساختار نواری گرافین و h-BN با استفاده از روش تنگابست

۳- محاسبه ساختار نواری گرافین و h-BN با استفاده از بسته محاسباتی PythTB

۴- بررسی شکست تقارن وارونی

```
from pythtb import *

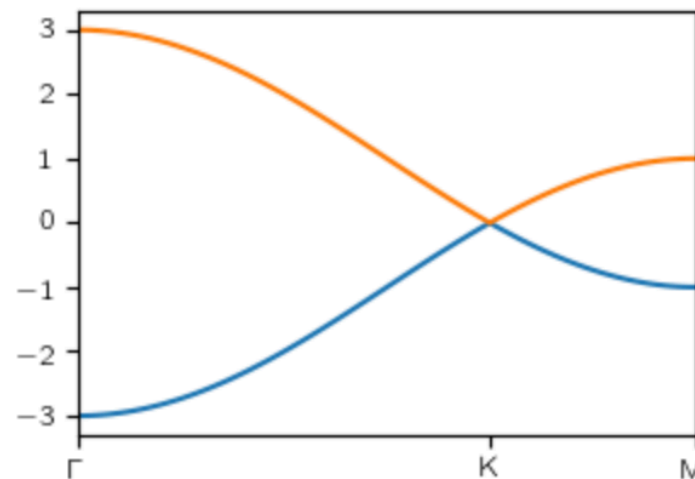
# lattice vectors and orbital positions
lat=[[1.0, 0.0], [0.5, np.sqrt(3.0)/2.0]]
orb=[[1./3., 1./3.], [2./3., 2./3.]]

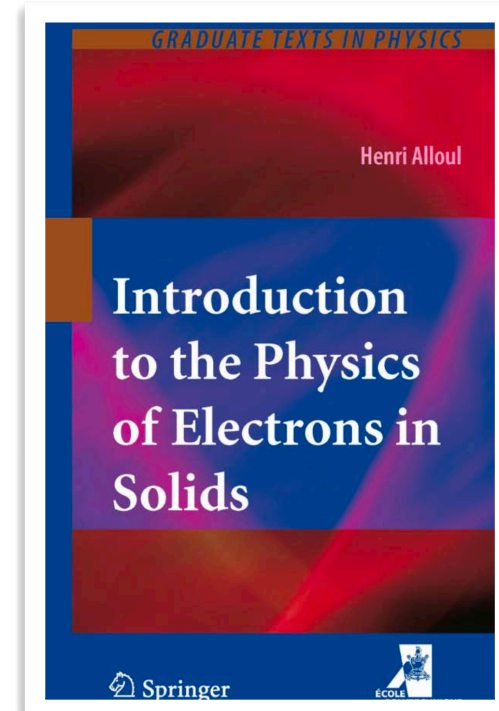
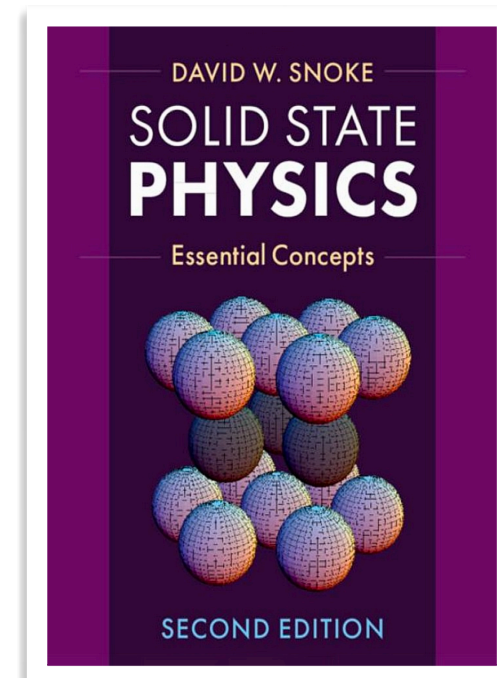
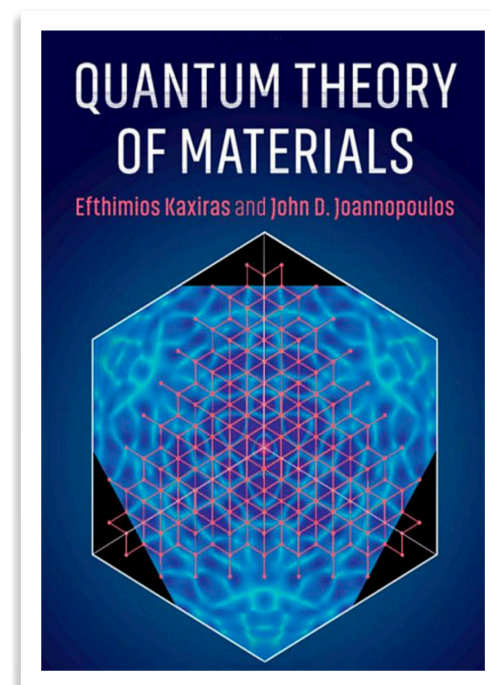
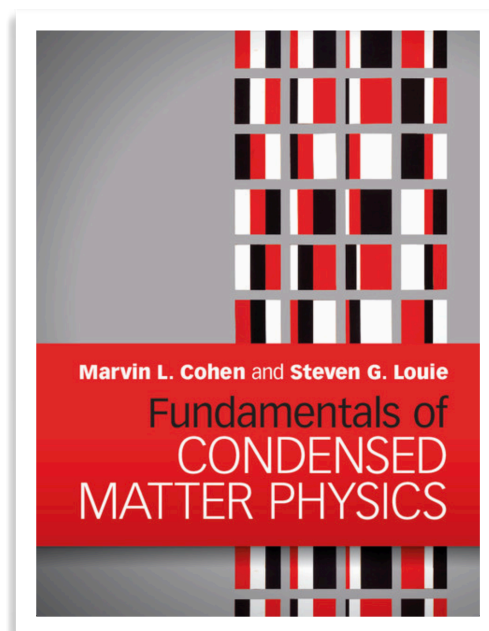
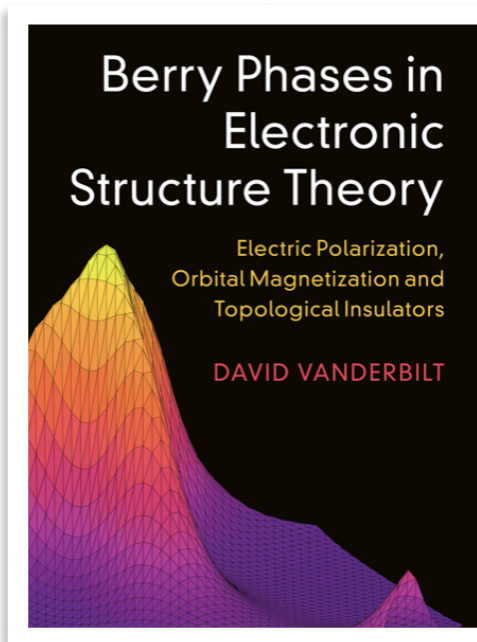
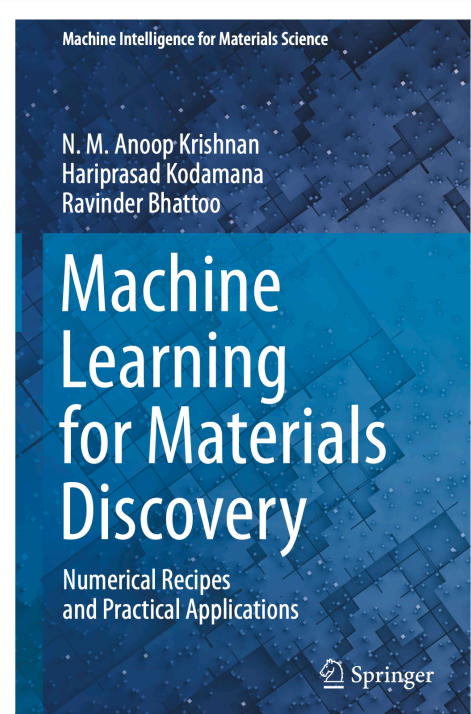
# two-dimensional tight-binding model
gra=tb_model(2, 2, lat, orb)

# define hopping between orbitals
gra.set_hop(-1.0, 0, 1, [ 0, 0])
gra.set_hop(-1.0, 1, 0, [ 1, 0])
gra.set_hop(-1.0, 1, 0, [ 0, 1])

# solve model on a path in k-space
k=[[0.0, 0.0],[1./3., 2./3.],[0.5,0.5]]
(k_vec,k_dist,k_node)=gra.k_path(k, 100)
evals=gra.solve_all(k_vec)

# plot bandstructure
import matplotlib.pyplot as plt
fig, ax = plt.subplots()
ax.plot(k_dist,evals[0,:])
ax.plot(k_dist,evals[1,:])
ax.set_xticks(k_node)
ax.set_xticklabels(["$\Gamma$", "K", "M"])
ax.set_xlim(k_node[0],k_node[-1])
fig.savefig("band.png")
```





Stefano Sanvito Lecture note

Highly anisotropic thermal conductivity of arsenene: An *ab initio* study

Majid Zeraati,¹ S. Mehdi Vaez Allaei,^{1,2,*} I. Abdolhosseini Sarsari,³ Mahdi Pourfath,^{4,5} and Davide Donadio^{6,7,8,9,†}

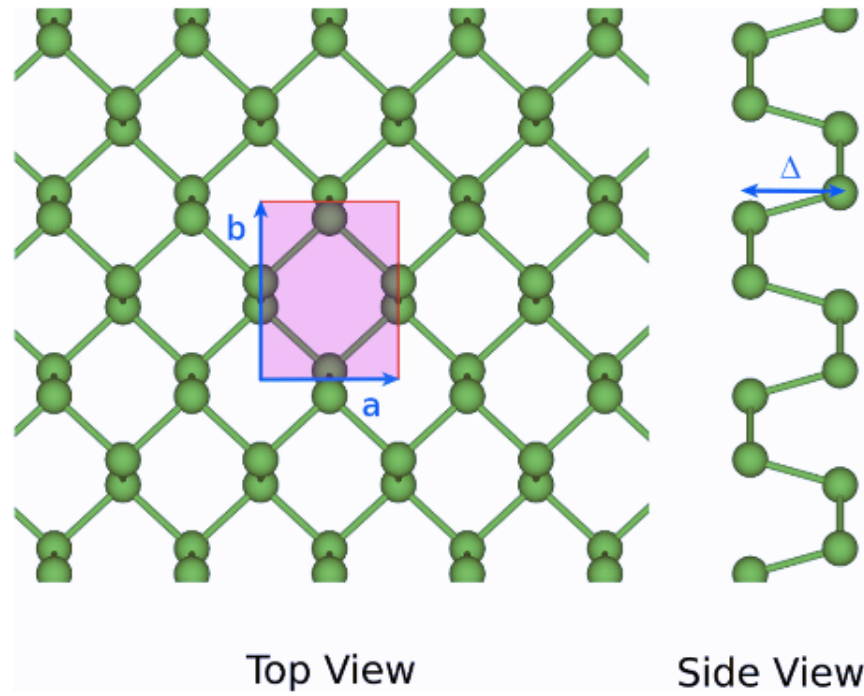


FIG. 1. Top and side views of puckered arsenene.

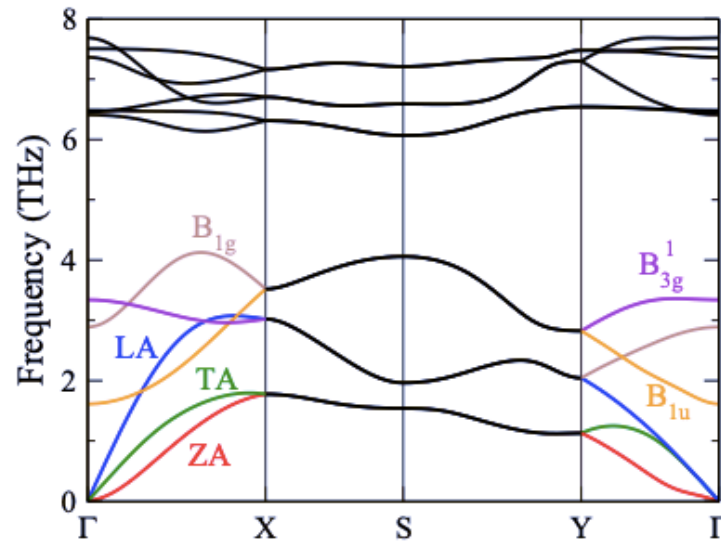
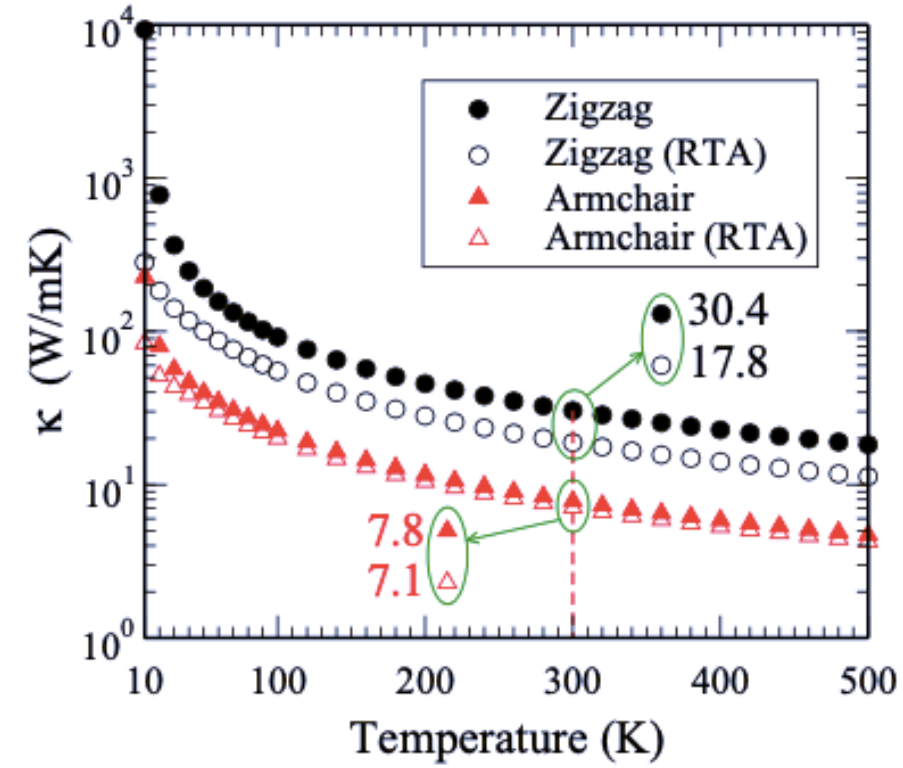
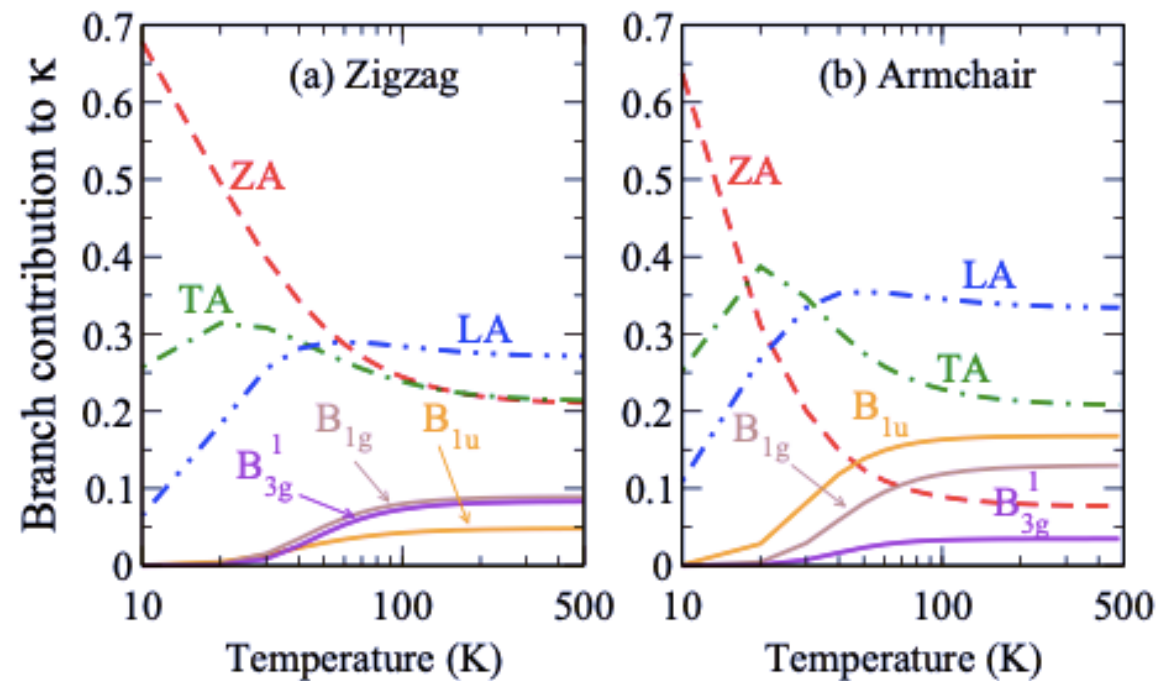


FIG. 2. Phonon dispersion curves along the high-symmetry directions of the first Brillouin zone for puckered arsenene.



Electronic Structure

PAPER

Electronic and interfacial properties of graphene/HfS₂ van der Waals heterostructure

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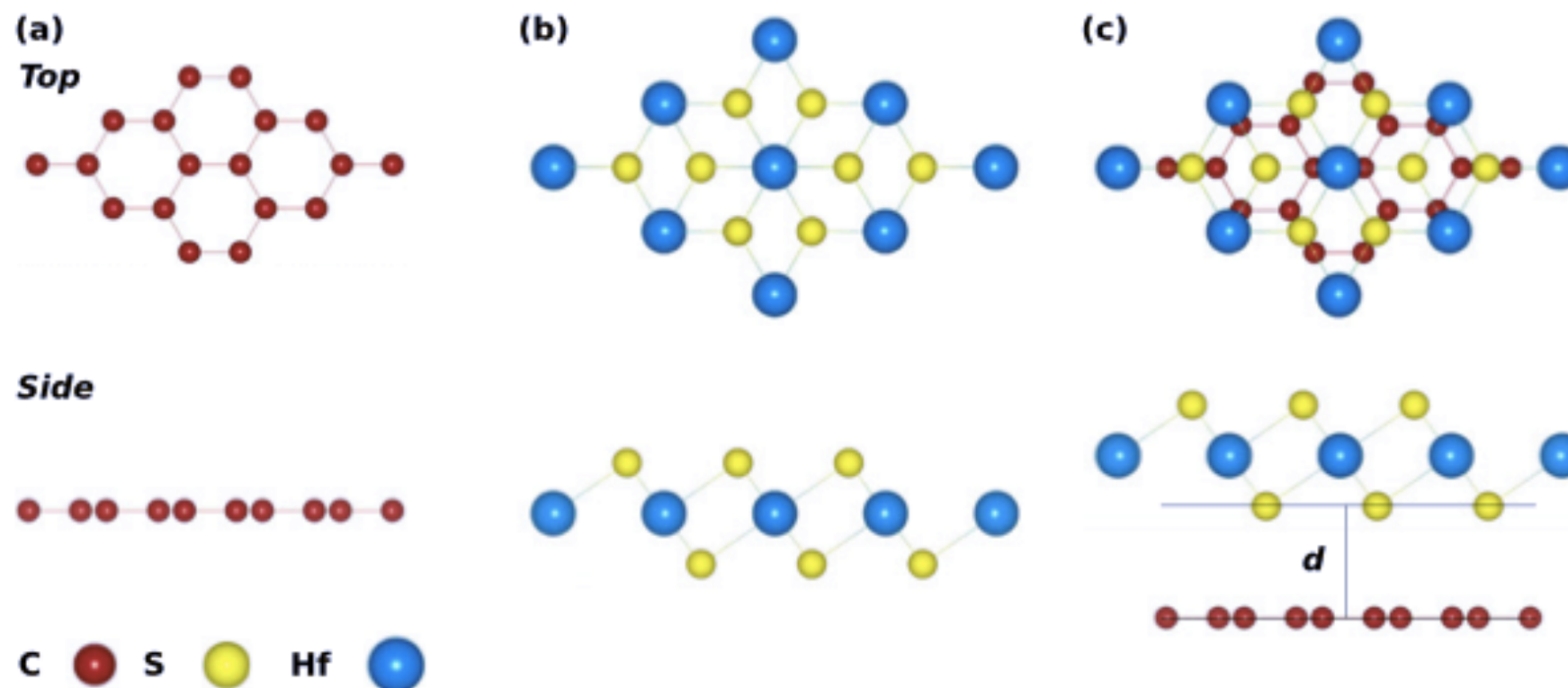


Figure 2. Schematic graphics of optimized crystalline structures of (a) $3 \times 3 \times 1$ supercell of graphene, (b) $2 \times 2 \times 1$ supercell of HfS₂ and (c) G/HfS₂ vdW heterostructure.

Theoretical study of quantum emitters in two-dimensional silicon carbide monolayers

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²*Department of Applied Physics, Aalto University, FI-00076 Aalto, Finland*

³*Department of Atomic Physics, Budapest University of Technology and Economics, Budafoki út 8, 1111 Budapest, Hungary*

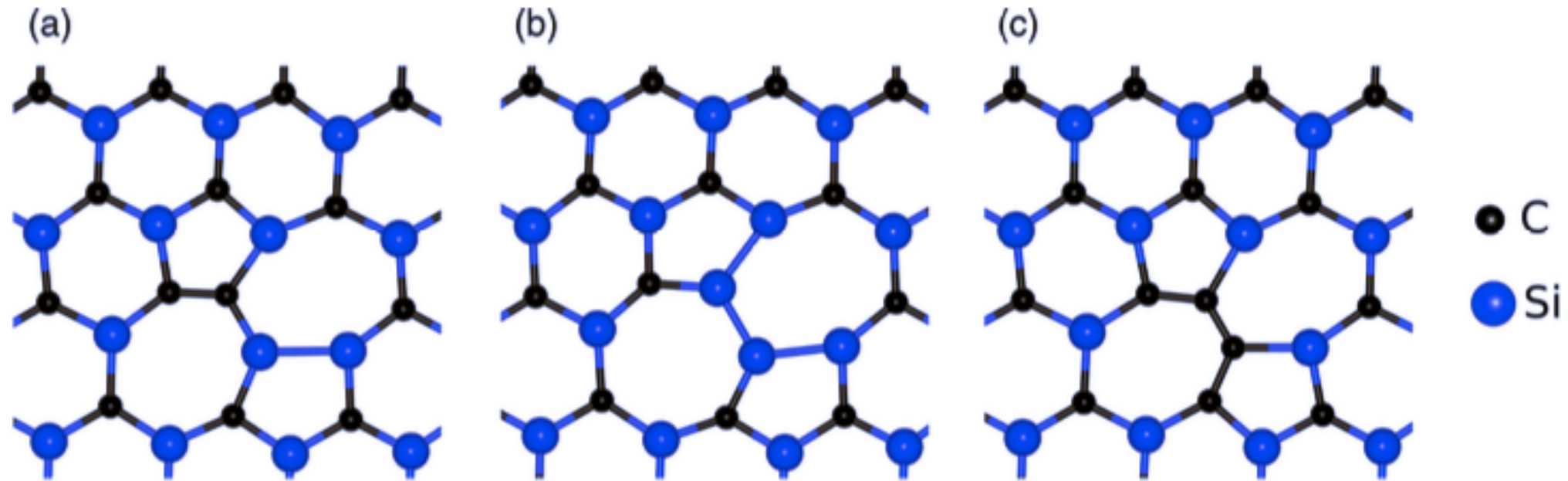
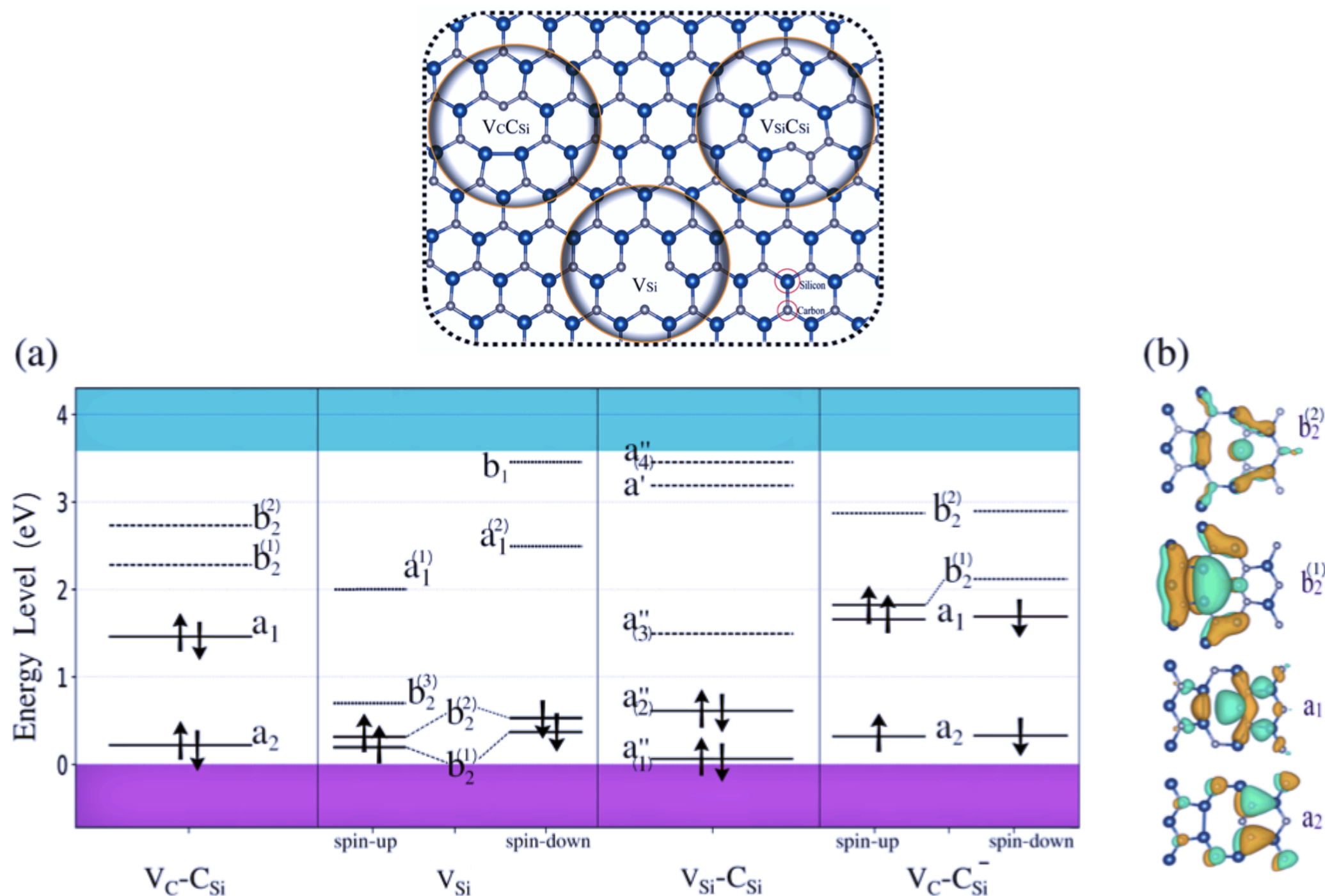


FIG. 1. Atomic structure of (a) SW, (b) SW-Si_C, and (c) SW-C_{Si} defects. Silicon and carbon atoms are illustrated by blue and black colors, respectively

Vacancy-related color centers in two-dimensional silicon carbide monolayers

M. Mohseni ^{1,2,3}, I. Abdolhosseini Sarsari ^{3,*}, S. Karbasizadeh ³, Péter Udvarhelyi,^{1,4} Q. Hassanzada ⁵,
 T. Ala-Nissila ^{6,7} and A. Gali ^{1,4,8,†}



PAPER

Strain induced coupling and quantum information processing with hexagonal boron nitride quantum emitters

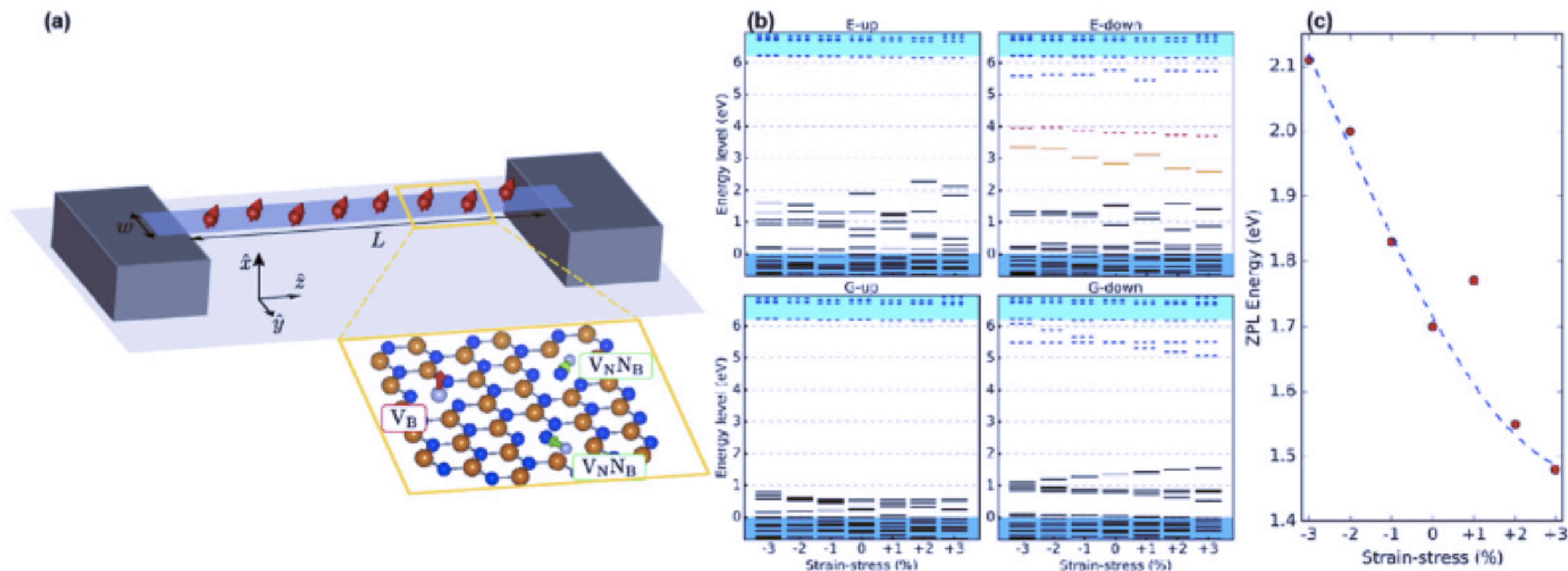
F T Tabesh¹ , Q Hassanzada^{1,2}, M Hadian¹, A Hashemi³, I Abdolhosseini Sarsari¹ 
and M Abdi^{1,*} 

¹ Department of Physics, Isfahan University of Technology, Isfahan 84156-83111, Iran

² Fritz-Haber-Institut der Max-Planck-Gesellschaft, Faradayweg 4-6, D-14195 Berlin, Germany

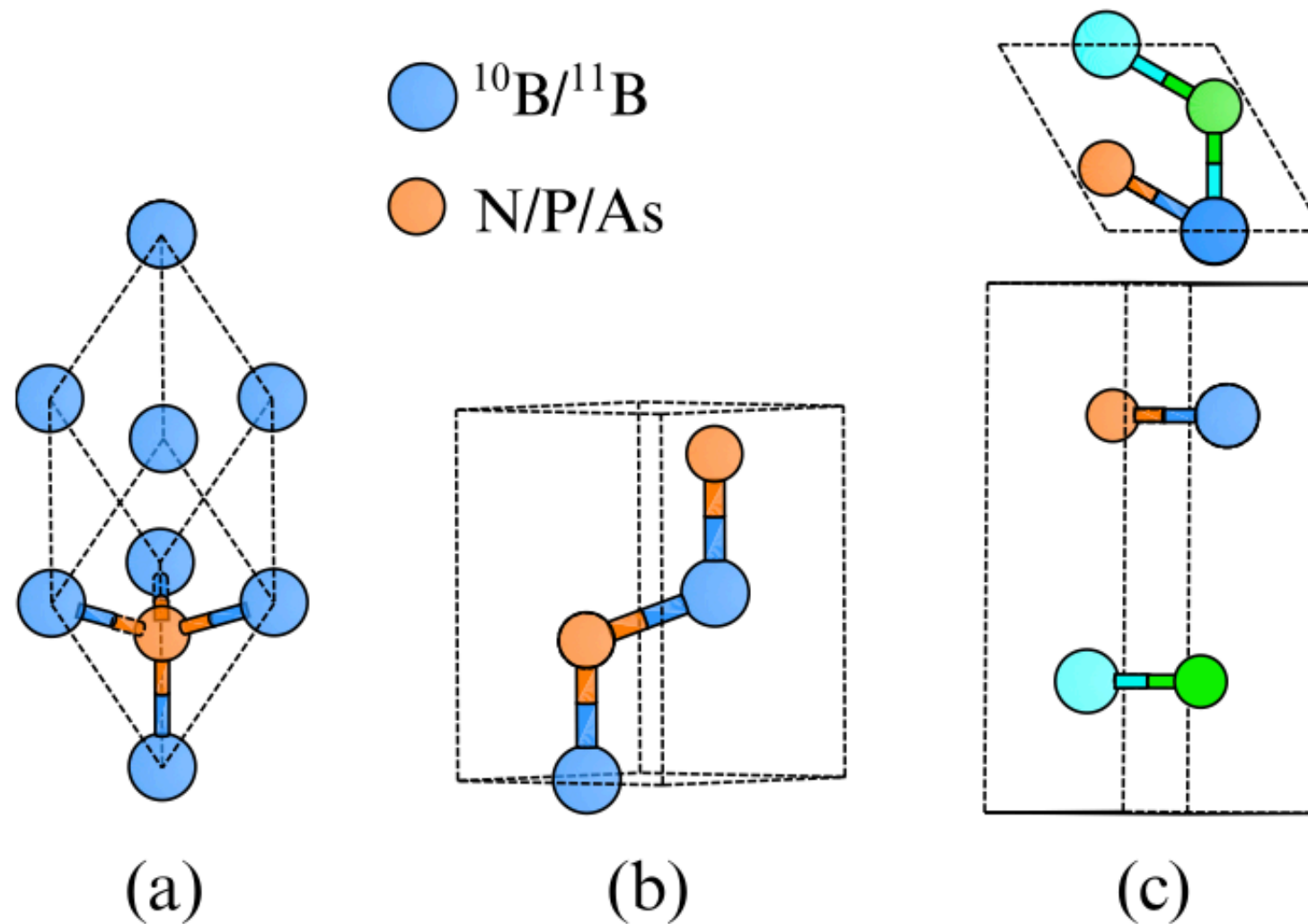
³ Department of Applied Physics, Aalto University, PO Box 11100, 00076 Aalto, Finland

* Author to whom any correspondence should be addressed.



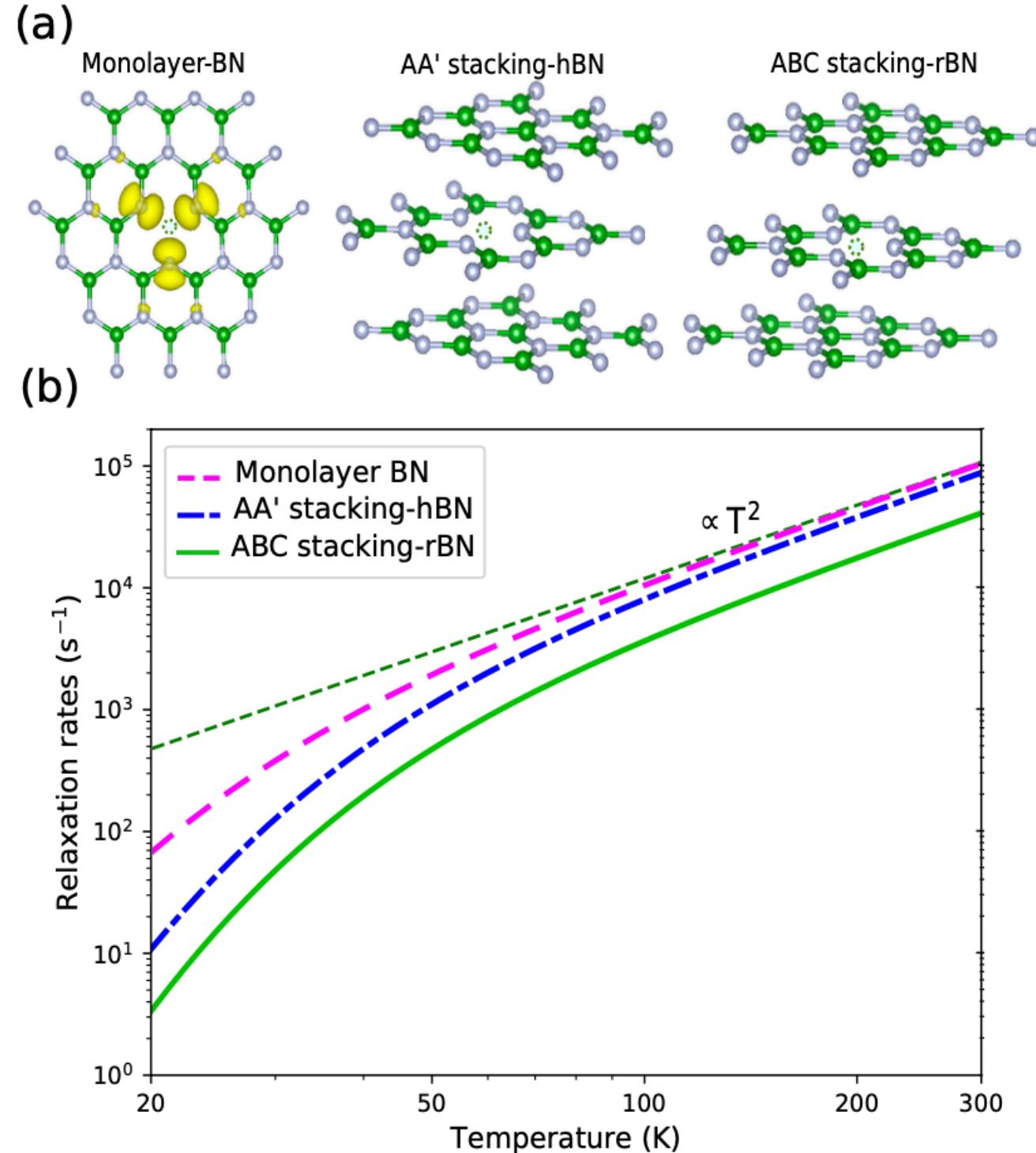
Boron isotope effects on Raman scattering in bulk BN, BP, and BAs: A density functional theory study

Nima Ghafari Cherati ^{1,2}, I. Abdolhosseini Sarsari ³, Arsalan Hashemi ^{4,*} and Tapio Ala-Nissila ^{4,5,†}



Spin-Phonon Relaxation of Boron-Vacancy Centers in Two-Dimensional Boron Nitride Polytypes

Nasrin Estaji,¹ Ismaeil Abdolhosseini Sarsari,¹ Gergő Thiering,² and Adam Gali^{2,3,4,*}





Ab Initio Quantum Electrodynamics for Quantum Materials Engineering

September 29, 2025 – October 3, 2025

Registration deadline: May 30, 2025

Location: Flatiron Institute, New York City, USA

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